

Solar Cells Reporting Summary

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► Experimental design

Please check: are the following details reported in the manuscript?

1. Dimensions

Area of the tested solar cells

Yes
 No

The "Characterization of solar cells" of "Methods"

Method used to determine the device area

Yes
 No

The "Characterization of solar cells" of "Methods"

2. Current-voltage characterization

Current density-voltage (J-V) plots in both forward and backward direction

Yes
 No

Figure 2c

Voltage scan conditions

For instance: scan direction, speed, dwell times

Yes
 No

The "Characterization of solar cells" of "Methods"

Test environment

For instance: characterization temperature, in air or in glove box

Yes
 No

Figure captions and "Characterization of solar cells" of "Methods"

Protocol for preconditioning of the device before its characterization

Yes
 No

These devices are tested directly without any preprocessing.

Stability of the J-V characteristic

Verified with time evolution of the maximum power point or with the photocurrent at maximum power point; see ref. 7 for details.

Yes
 No

Figure 5e and Supplementary Figure 5

3. Hysteresis or any other unusual behaviour

Description of the unusual behaviour observed during the characterization

Yes
 No

Section "PV performance of CsPbI_{3-x}Br_x PSCs employing dipole layers"

Related experimental data

Yes
 No

Figure 2c and Table 1

4. Efficiency

External quantum efficiency (EQE) or incident photons to current efficiency (IPCE)

Yes
 No

Figure 2b and Figure 5d

A comparison between the integrated response under the standard reference spectrum and the response measured under the simulator

Yes
 No

The integrated J_{sc} values from QE were consistent with J_{sc} values from J-V measurements.

For tandem solar cells, the bias illumination and bias voltage used for each subcell

Yes
 No

The "Characterization of solar cells" of "Methods"

5. Calibration

Light source and reference cell or sensor used for the characterization

Yes
 No

The "Characterization of solar cells" of "Methods"

Confirmation that the reference cell was calibrated and certified

Yes
 No

The "Characterization of solar cells" of "Methods"

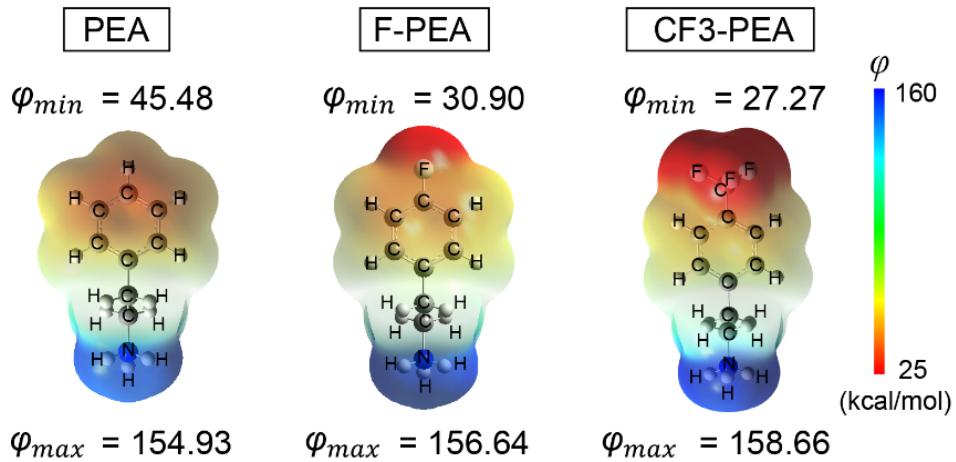
<p>Calculation of spectral mismatch between the reference cell and the devices under test</p> <p>6. Mask/aperture</p> <p>Size of the mask/aperture used during testing</p> <p>Variation of the measured short-circuit current density with the mask/aperture area</p> <p>7. Performance certification</p> <p>Identity of the independent certification laboratory that confirmed the photovoltaic performance</p> <p>A copy of any certificate(s) <i>Provide in Supplementary Information</i></p> <p>8. Statistics</p> <p>Number of solar cells tested</p> <p>Statistical analysis of the device performance</p> <p>9. Long-term stability analysis</p> <p>Type of analysis, bias conditions and environmental conditions <i>For instance: illumination type, temperature, atmosphere humidity, encapsulation method, preconditioning temperature</i></p>	<p><input type="checkbox"/> Yes <input checked="" type="checkbox"/> No</p> <p>The light spectrum used for measurements matches well with the reference silicon cell, and we did not calculate the spectral mismatch between the reference cell and the tested devices</p> <p><input checked="" type="checkbox"/> Yes <input type="checkbox"/> No</p> <p>The "Characterization of solar cells" of "Methods"</p> <p><input type="checkbox"/> Yes <input checked="" type="checkbox"/> No</p> <p>We measured all devices with masks.</p> <p><input type="checkbox"/> Yes <input checked="" type="checkbox"/> No</p> <p>The focus of this paper is to improve the stability of tandems using an inorganic wide-bandgap subcell. In addition, the reliability of the two-lamp high spectral match solar simulator (SAN-EI ELECTRIC, XHS-50S1) has been confirmed, so the certification is not necessary for this work.</p> <p><input type="checkbox"/> Yes <input checked="" type="checkbox"/> No</p> <p>No certificate</p> <p><input checked="" type="checkbox"/> Yes <input type="checkbox"/> No</p> <p>Stated in the manuscript.</p> <p><input checked="" type="checkbox"/> Yes <input type="checkbox"/> No</p> <p>Stated in the manuscript.</p> <p><input checked="" type="checkbox"/> Yes <input type="checkbox"/> No</p> <p>The "Operational stability tests of solar cells" of "Methods"</p>
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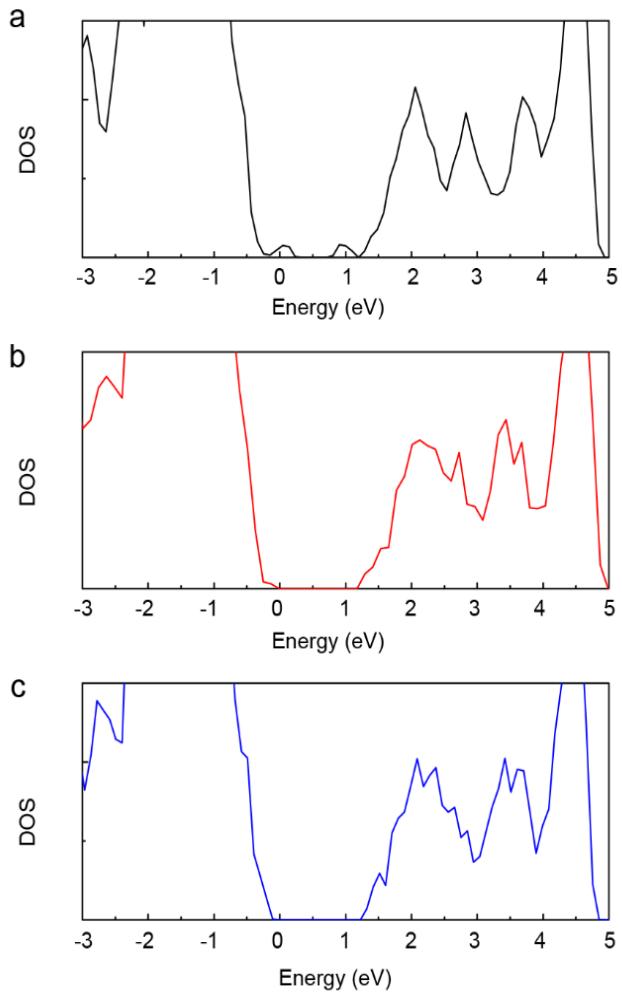
Inorganic wide-bandgap perovskite subcells with dipole bridge for all-perovskite tandems

In the format provided by the
authors and unedited

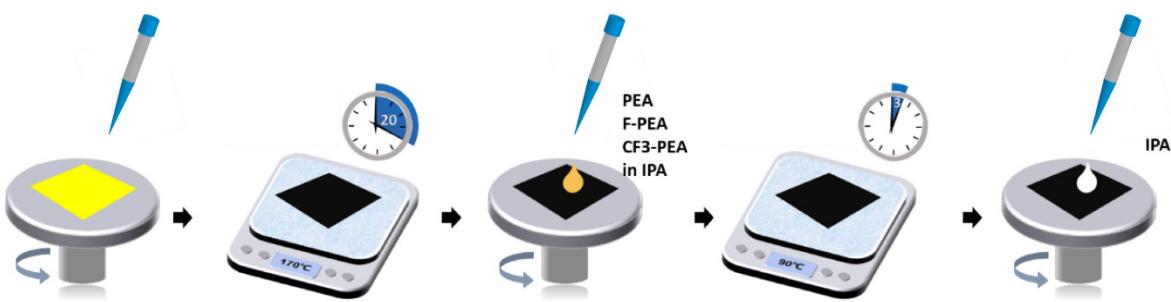
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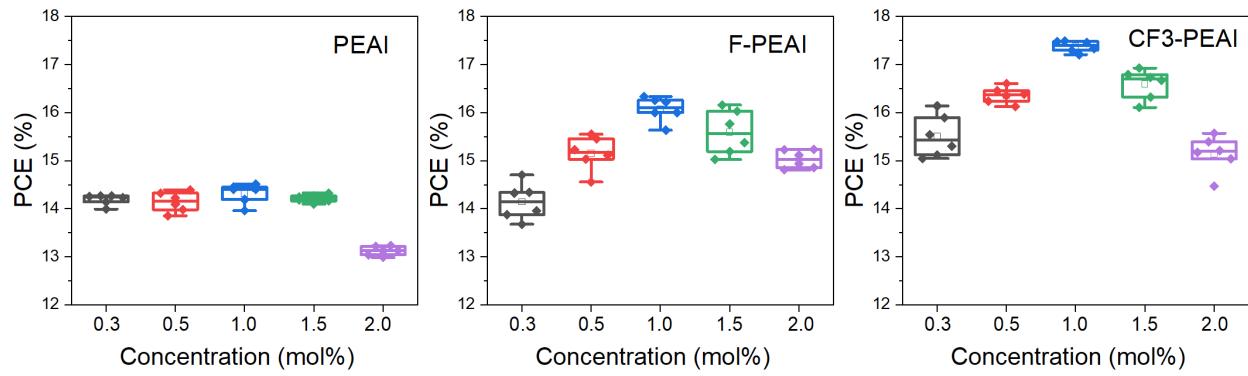




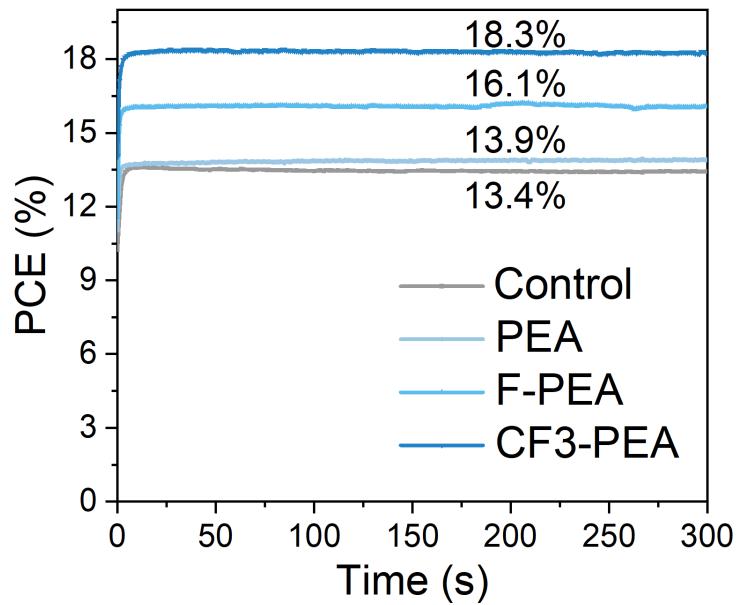
Supplementary Figure 2. Density of states (DOS) of the Pb-I terminated CsPbI_3 perovskite surface containing I_{Pb} antisite defect (a) control, (b) CF3-PEA, and (c) PEA cationic passivator treatment.



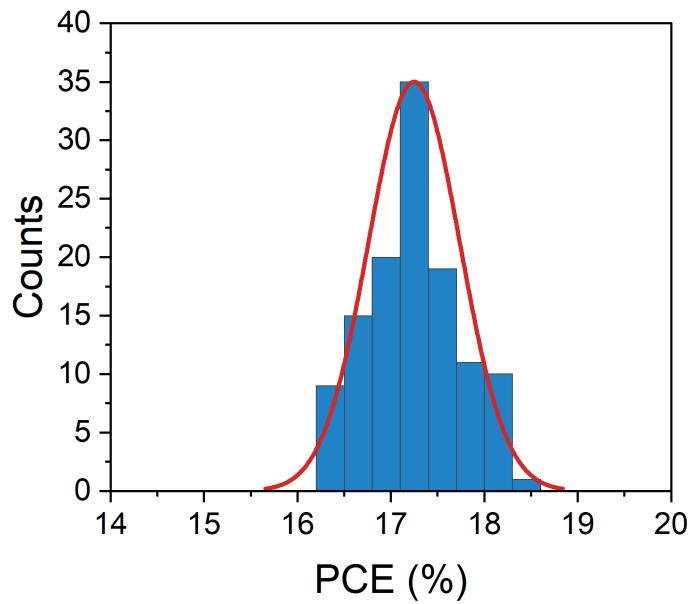
Supplementary Figure 3. Schematic illustration of the fabrication process of passivated $\text{CsPbI}_{3-x}\text{Br}_x$ films.



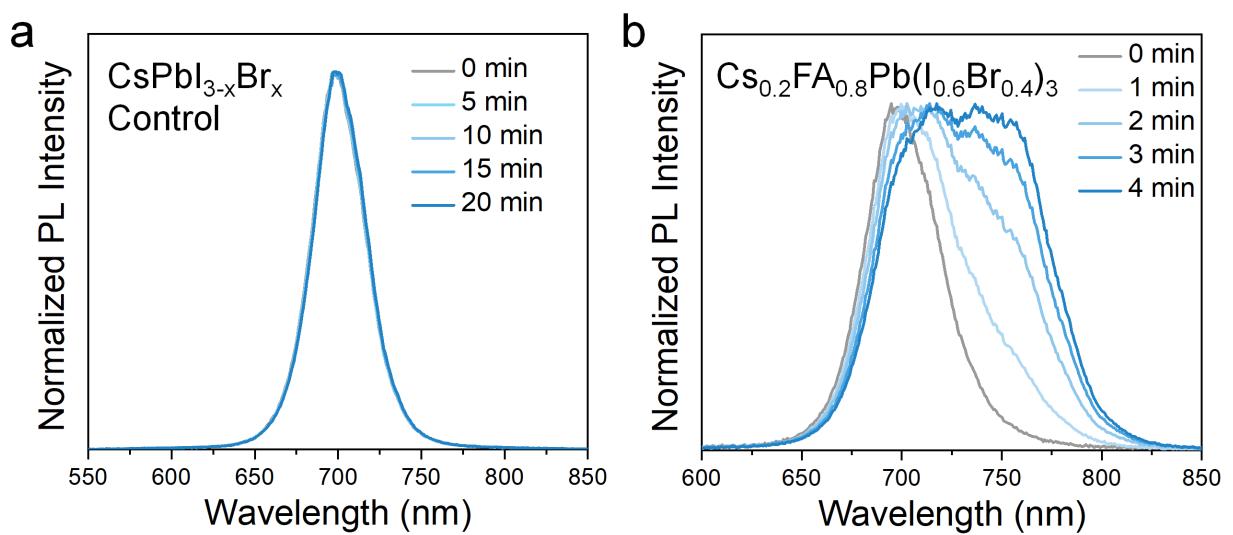
Supplementary Figure 4. PCEs of $\text{CsPbI}_{3-x}\text{Br}_x$ perovskite solar cells with various concentrations of passivation molecules (6 devices for each concentration). a, PEA; b, F-PEA; c, CF3-PEA. The box plot denotes median (centre line), 75th (top edge of the box), 25th (bottom edge of the box) percentiles. The solid dots represent each device datum.



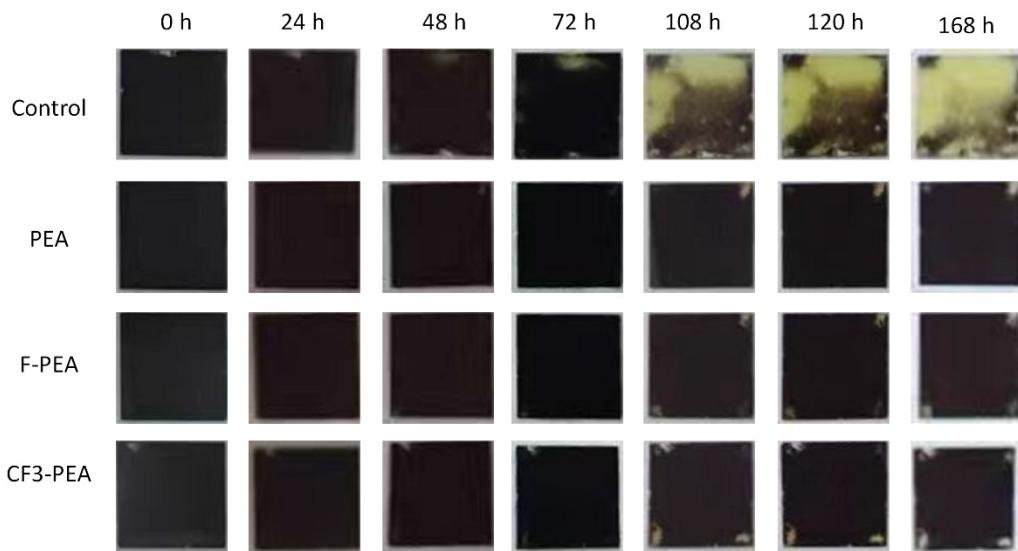
Supplementary Figure 5. Stabilized power output of the four champion devices.



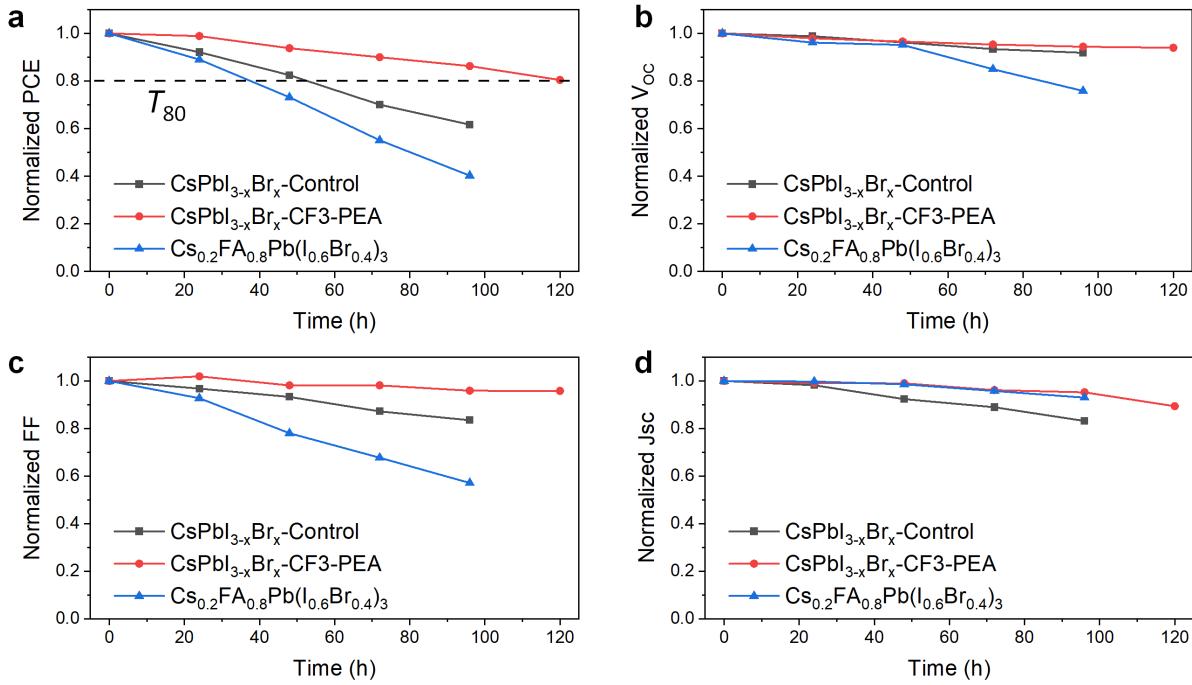
Supplementary Figure 6. Histogram of PCEs over 120 CF3-PEA passivated devices. The devices exhibit an average PCE of $17.3 \pm 0.5\%$.



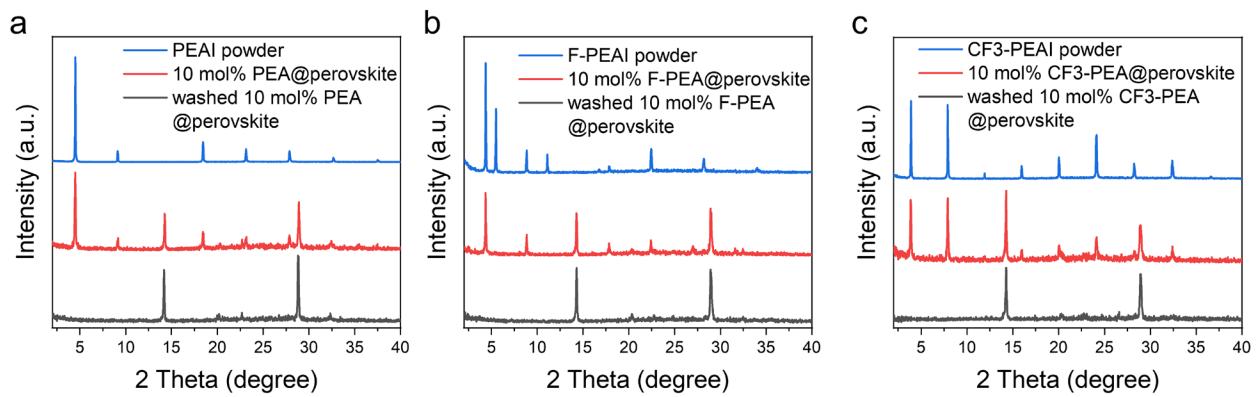
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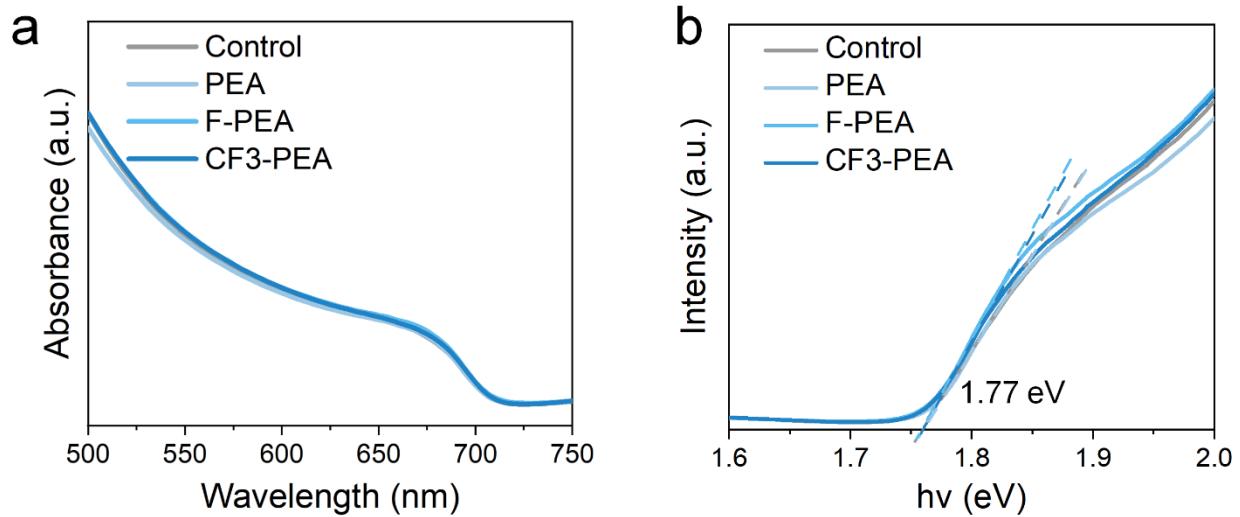
Supplementary Figure 8. Phase transition process of perovskite films under heating at 85°C. After heating at 85°C for 108 hours, the control film in this work has visibly begun to convert to the yellow phase. Surface treatments improves the phase stability of the film at 85°C. After 168 hours of heating, the black phase is maintained, revealing that perovskites with higher surface quality improve the thermal stability.



Supplementary Figure 9. PV performance evolution of unencapsulated device heated on an 85°C hotplate in a N₂ glove box. The J_{SC} of inorganic PSCs reflects a decrease in optical activity of the film. The CsPbI_{3-x}Br_x, CsPbI_{3-x}Br_x-CF3-PEA and Cs_{0.2}FA_{0.8}Pb(I_{0.6}Br_{0.4})₃ devices had initial PCEs of 13.3%, 16.5% and 16.8%, respectively.

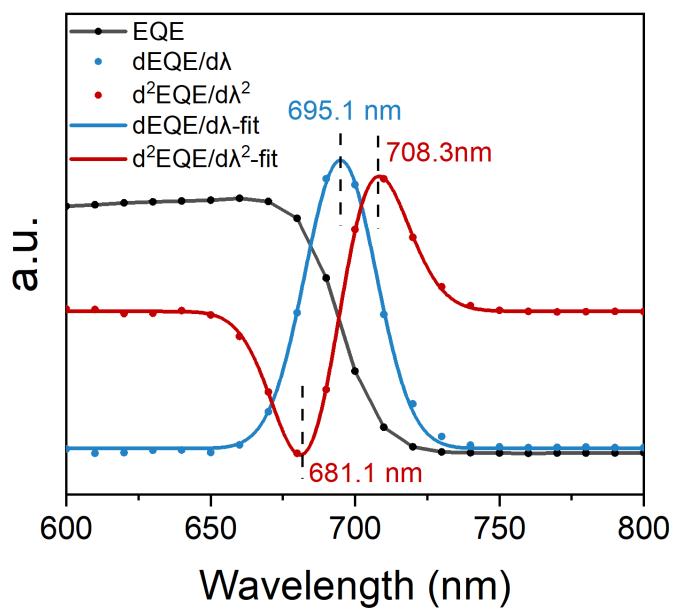


Supplementary Figure 10. XRD patterns of inorganic perovskite films with 10 mol% concentration of passivators, IPA washed films and the passivation molecules.

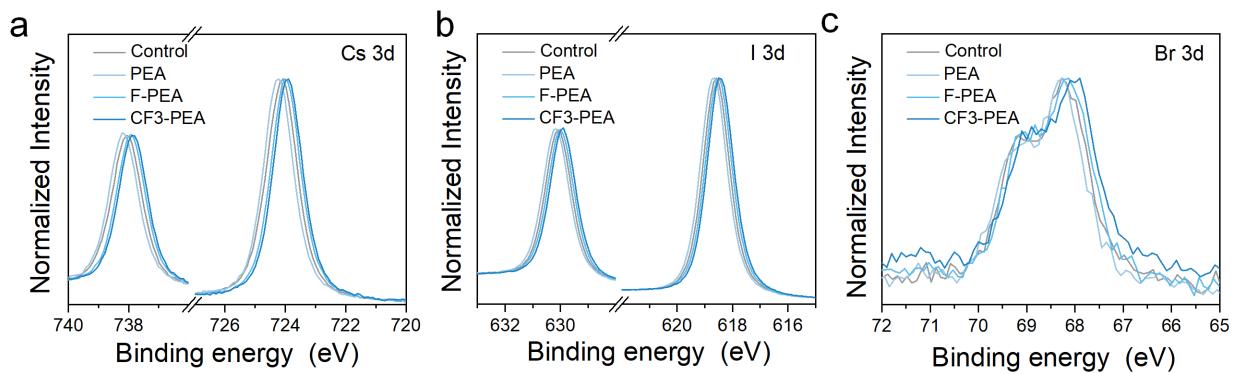


Supplementary Figure 11. UV-vis absorption spectra and the the optical bandgap of perovskite films.

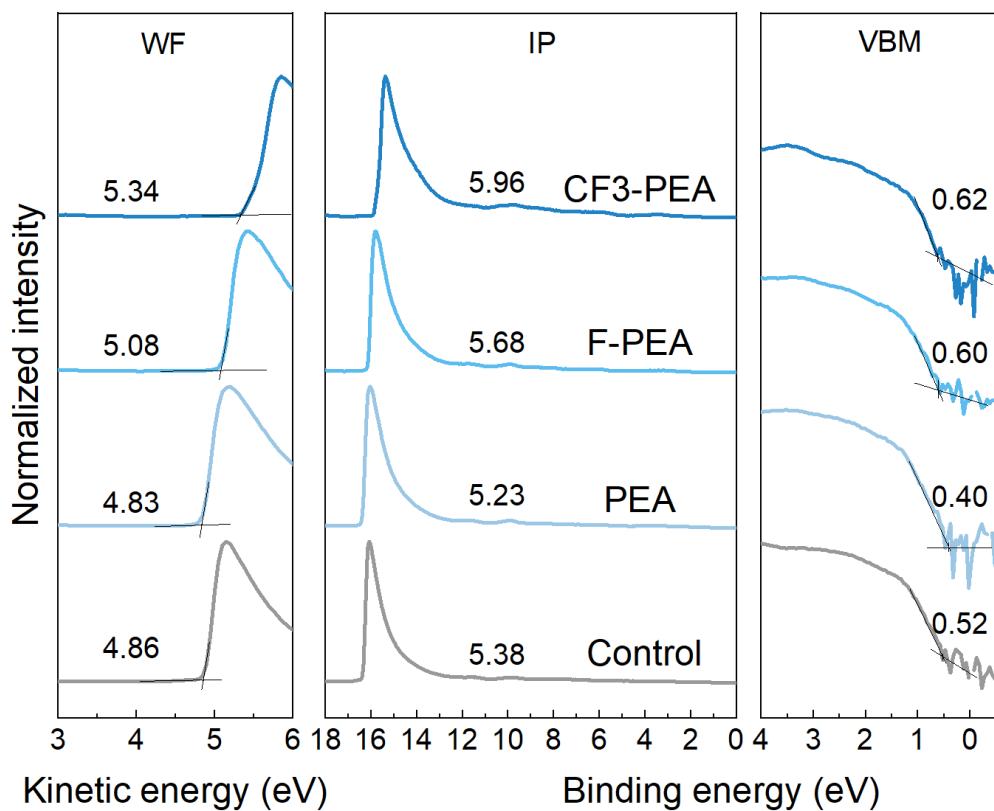
The dotted lines were used to calculate the band gaps.



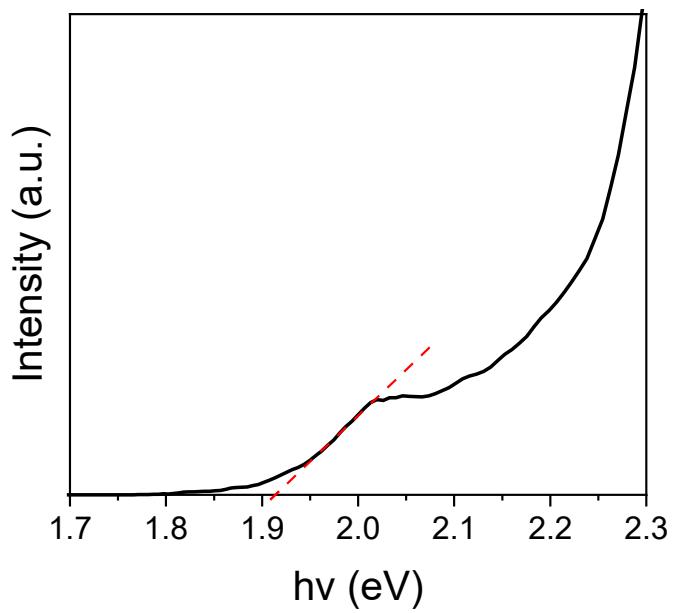
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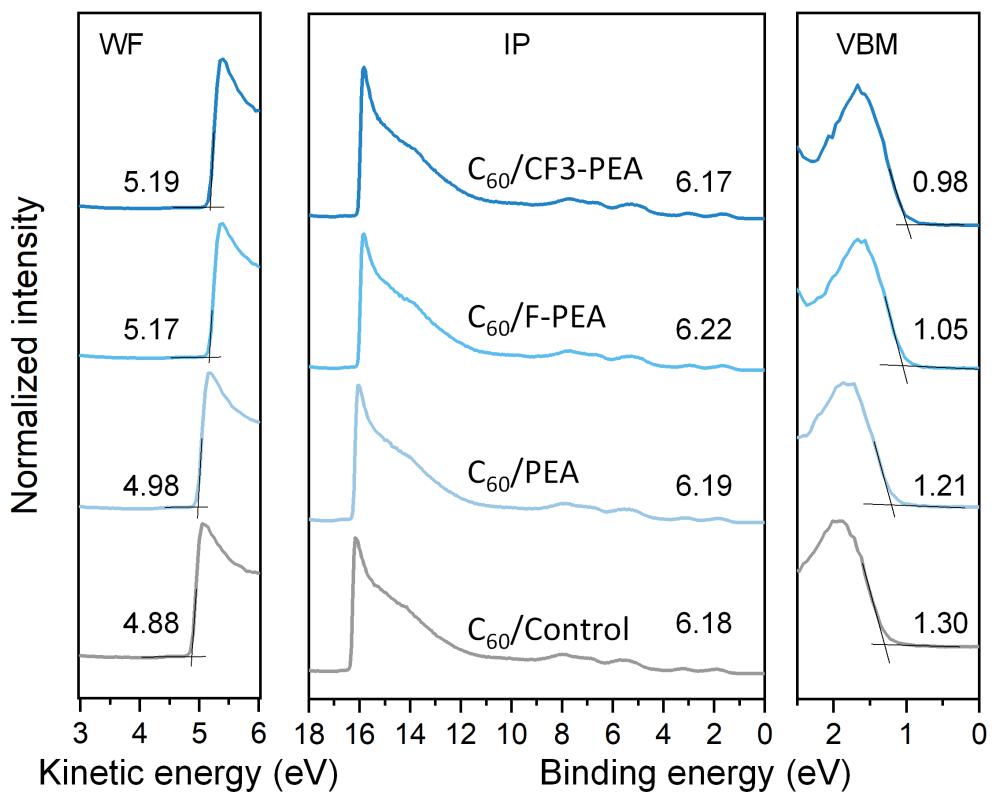
Supplementary Figure 13. XPS measurements of the perovskite films. (a) Cs 3d, (b) I 3d and (c) Br 3d, XPS core level spectra of the perovskite films.



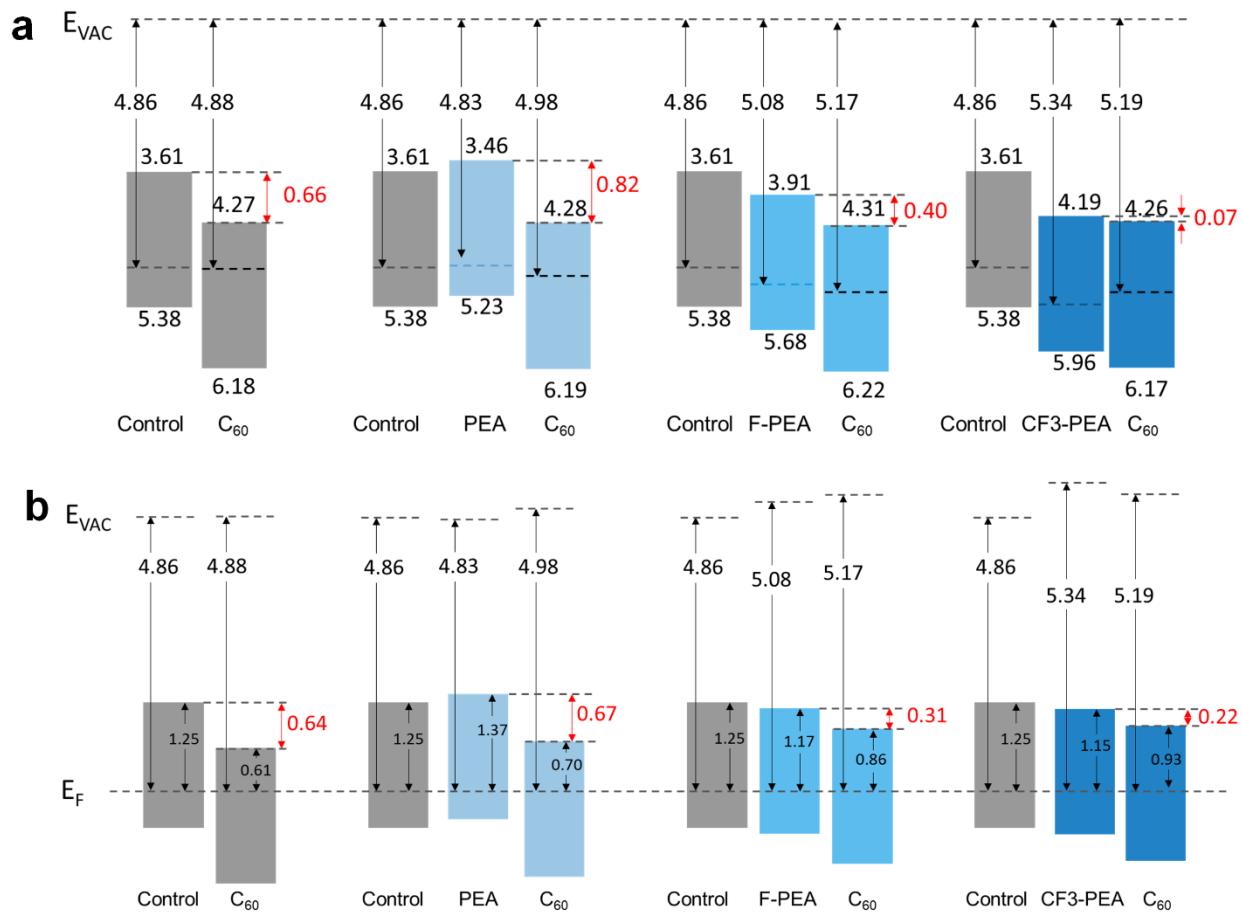
Supplementary Figure 14. UPS spectra at the secondary electron cutoff region and the frontier electronic structure region of the perovskite films. The values of WF and VBM were determined by the intersections of tangents.



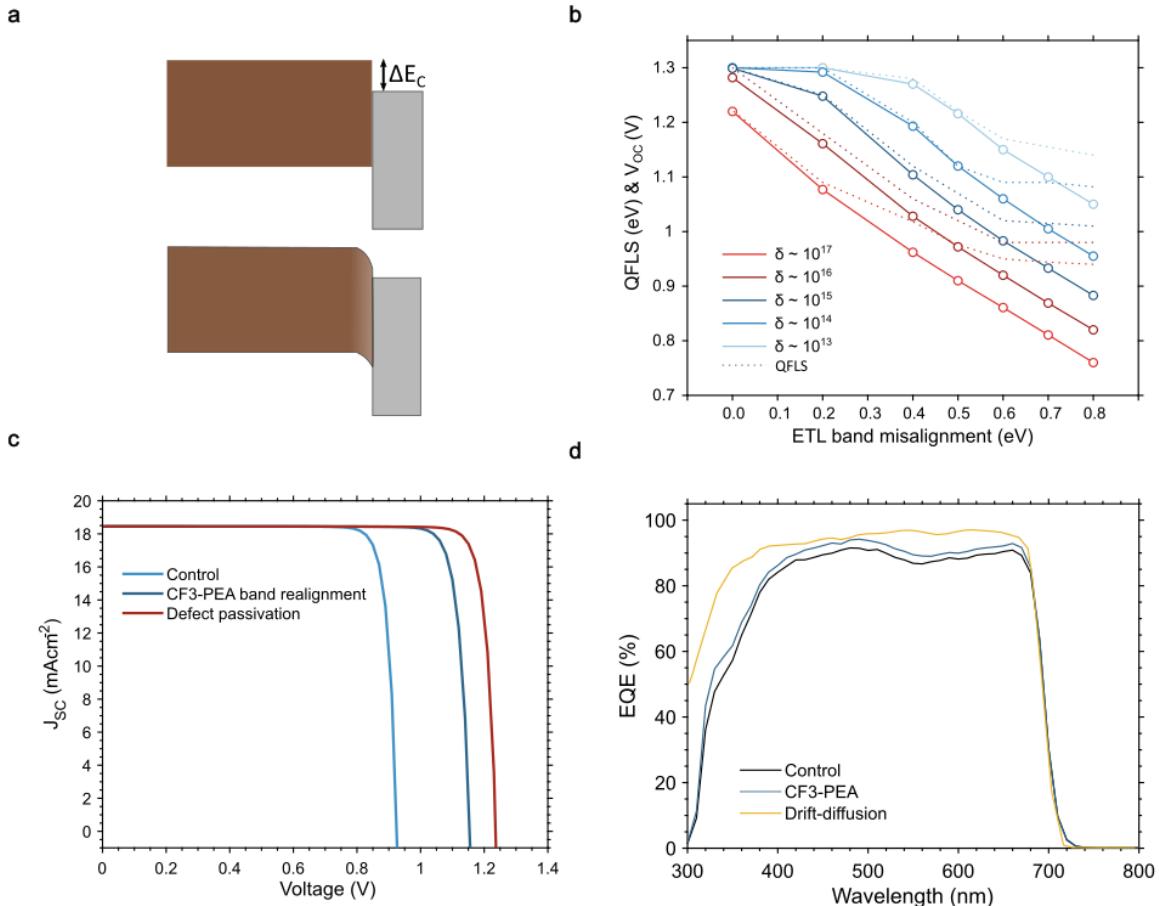
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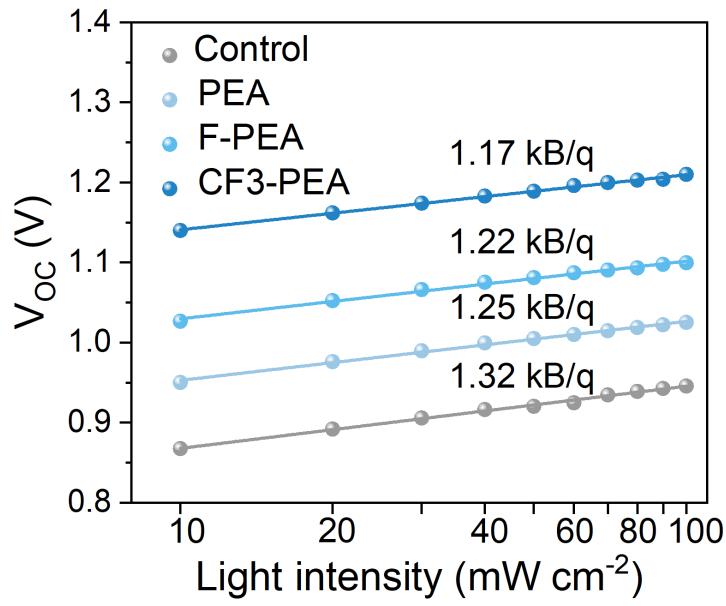
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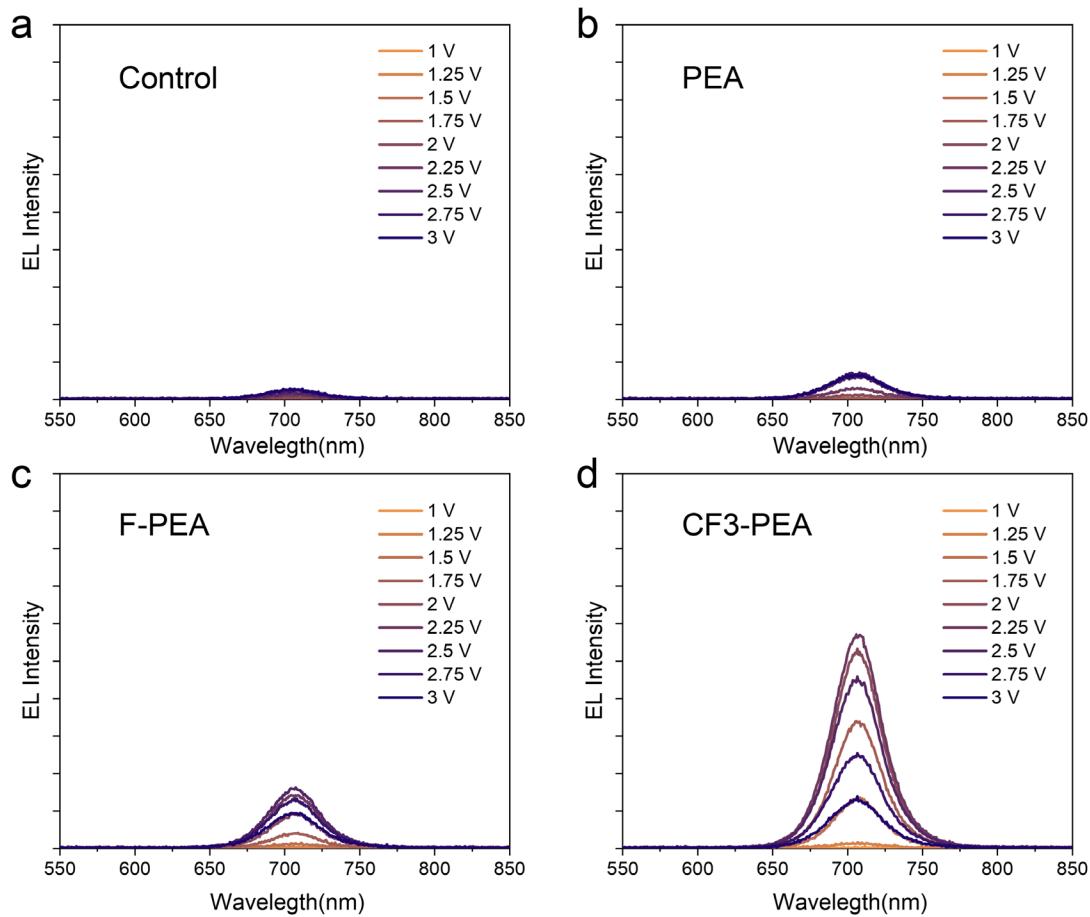
Supplementary Figure 17. **a**, Energy level diagram of the perovskite films and C_{60} coated on the corresponding perovskite, reference to vacuum level. **b**, Energy level diagram of the perovskite films and C_{60} coated on the corresponding perovskite, reference to Fermi level.



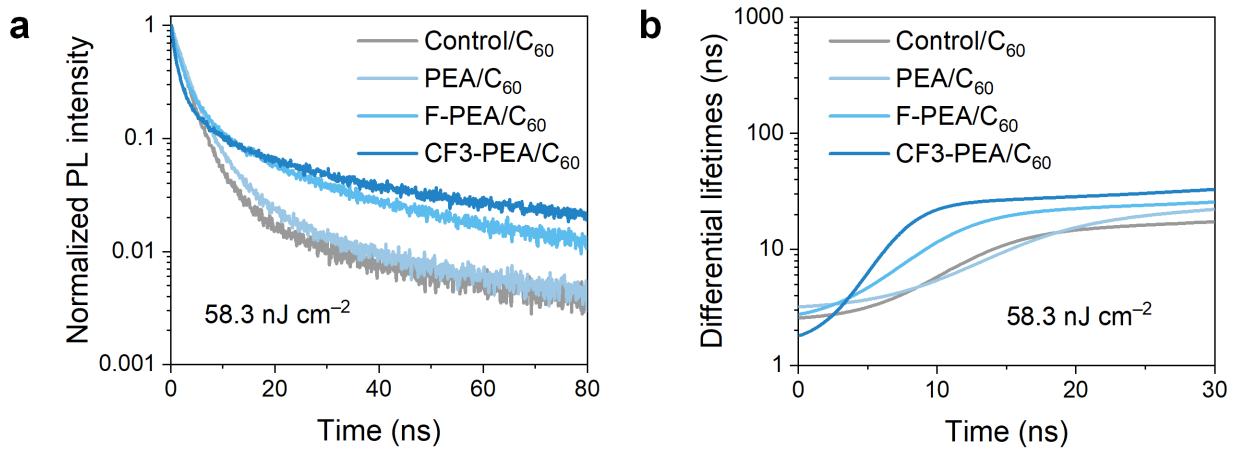
Supplementary Figure 18. Drift diffusion modelling using SCAPS-1D. **a**, ΔE_C is the energy level misalignment between perovskite (brown) and the C_{60} (grey). Treating the surface of the perovskite with the organics causes the first few nm of film to realign. **b**, The dependence of bulk QFLS in the perovskite absorber and V_{OC} of the cell with surface trap state density (δ) and ETL energetic misalignment (ΔE_C). For low levels of perovskite/ETL misalignment, there is a strong correlation between QFLS and V_{OC} . For larger band misalignment, the QFLS begins to taper to a fixed value. Reducing the offset between perovskite and ETL with the CF3-PEA treatment will increase the V_{OC} of devices dramatically regardless of defect density, however this effect is increased for higher defect densities. **c**, Resultant J - V curves based on a control with a $\Delta E_C = 0.64$ and an interfacial defect density of 10^{16} (equivalent to a surface recombination velocity of $\sim 10^3$ cm/s⁹) and a CF3-PEA treated device with a $\Delta E_C = 0.22$ and an interfacial defect density of 10^{15} (equivalent to a surface recombination velocity of ~ 100 cm/s). **d**, Comparison of true device EQE and EQE from simulations showing that significant charge lost in the device is uncounted for by the simulations. A possible cause is a poor-quality interface which does not extract charge as efficiently across the entire film. The parameters used for simulation are found in Table S6-7 below.



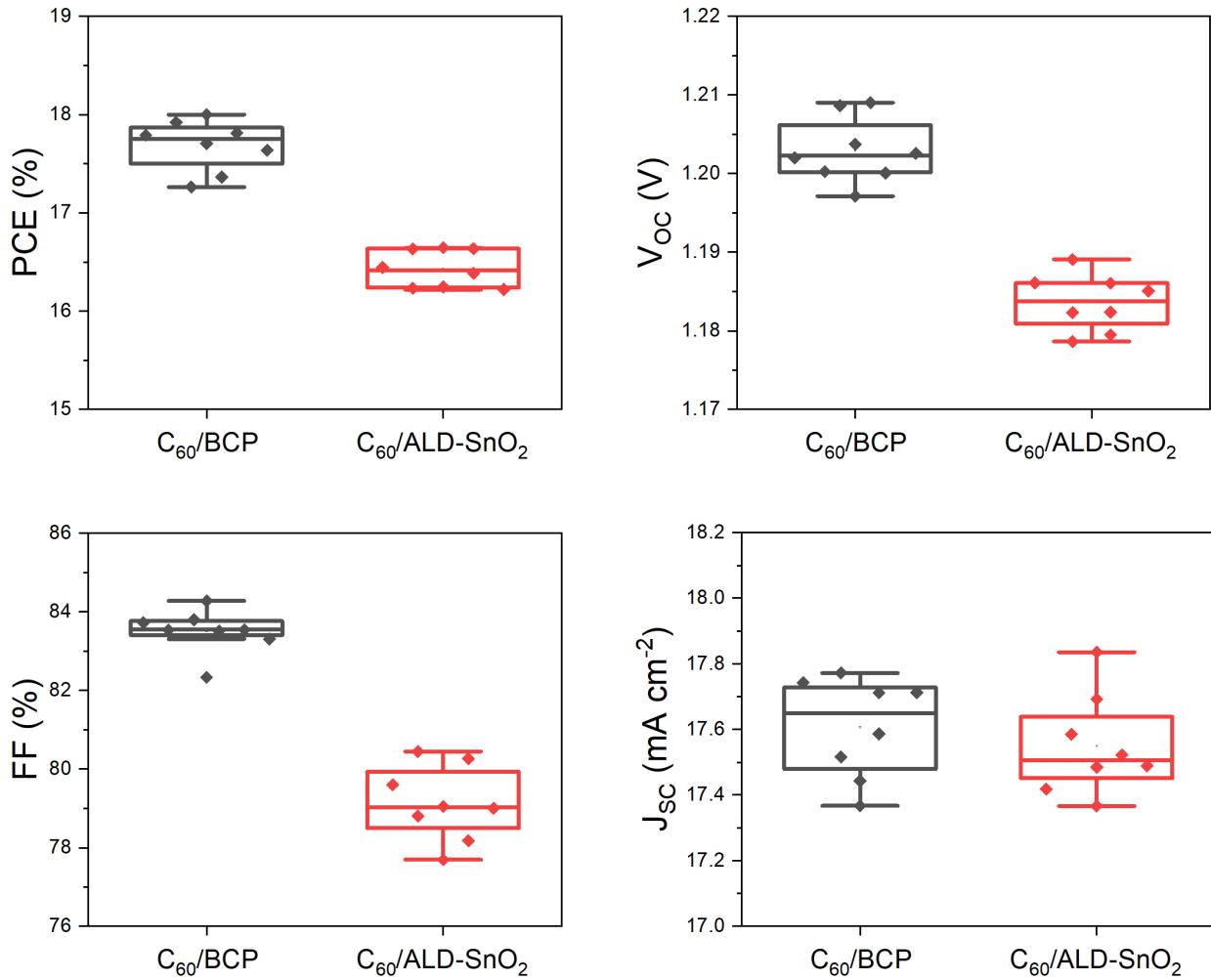
Supplementary Figure 19. V_{OC} versus light intensity of the devices. The solid lines are the corresponding data fitting curves.



Supplementary Figure 20. EL spectra of PSCs based on control, PEA, F-PEA and CF3-PEA.



Supplementary Figure 21. TRPL spectra and computed differential lifetimes with excitation fluence of 58.3 nJ cm⁻².



Supplementary Figure 22. The loss of device performance parameters after the deposition of SnO_2 in the tunneling junction by atomic layer deposition (75°C vacuum environment). The box plot denotes median (centre line), 75th (top edge of the box), 25th (bottom edge of the box) percentiles. The solid dots represent each device datum (8 devices for each type).

Supplementary Table 1. The detail photovoltaic parameters of champion n-i-p and p-i-n type CsPbX_3 perovskite solar cells.

Type	Perovskite	Structure	E_g (eV)	V_{oc} (V)	V_{oc} loss (V)	FF (%)	J_{sc} (mA cm^{-2})	PCE (%)	Ref.
n-i-p	CsPbI ₃	FTO/TiO ₂ /CsPbI ₃ /spiro-OMeTAD/Au	1.7	1.20	0.50	84.1	20.8	21.0	1
	CsPbI ₂ Br	FTO/c-TiO ₂ /mp-TiO ₂ /M:CsPbI ₂ Br/P ₃ HT/Au	1.91	1.33	0.58	80.1	16.34	17.45	2
	CsPbIBr ₂	ITO/TiO ₂ /CsPbIBr ₂ /PC ₆₁ B M/P3HT/Au	2.08	1.31	0.77	74.5	11.79	11.54	3
p-i-n	CsPbI ₃	ITO/P3CTN/CsPbI ₃ /PCBM/Au	1.68	1.21	0.47	80.4	19.72	19.84	4
	CsPbI ₂ Br	ITO/P3CTN/CsPbI ₂ Br/PCB M/C ₆₀ /BCP/Ag	1.88	1.22	0.66	79.6	16.4	15.9	5
	CsPbIBr ₂	ITO/NiO/MoS ₂ /CsPbIBr ₂ /Nb ₂ O ₅ /Ag	2.03	1.29	0.74	69.5	12.29	10.98	6
	CsPbI _{3-x} Br _x	ITO/NiO/SAM/CsPbI _{3-x} Br _x /BCP/Cu	1.77	1.23	0.54	82.8	18.1	18.5	This work

Supplementary Table 2. Gaussian calculated dipole moments for the neutral molecules (PEA, F-PEA and CF3-PEA).

Species	Dipole moment (D)
PEA (neutral)	1.31
F-PEA (neutral)	2.00
CF3-PEA (neutral)	3.38

Supplementary Table 3. The HSE+SOC calculated work function (WF) of a perovskite surface treated with three passivators (PEA, F-PEA and CF3-PEA). The mixing parameter (α) of the Hartree-Fock term in HSE+SOC calculations was set to 0.45. DFT-D3 method was used for the van der Waals (vdW) correction. The values obtained from experimental UPS data were also listed for comparison.

Passivators	HSE+SOC calculated WF	Experimental WF
bare	4.80	4.86
PEA	4.77	4.83
F-PEA	5.29	5.08
CF3-PEA	5.65	5.34

Supplementary Table 4. The HSE+SOC calculated CBM positions of a perovskite surface treated with three passivators (PEA, F-PEA and CF3-PEA) with respect to the CBM position of the bare surface. The values obtained from experimental UPS data were also listed for comparison.

Passivators	HSE+SOC calculations	Experiments
bare	0	0
PEA	0.13	0.15
F-PEA	-0.31	-0.30
CF3-PEA	-0.64	-0.58

Supplementary Table 5. Binding energy and shift of elements in perovskites.

Samples	Binding energy (eV)							
	Pb		Cs		I		Br	
Control	142.92	138.06	738.07	724.12	630.09	618.59	69.29	68.19
PEA	143.00	138.15	738.17	724.23	630.18	618.68	69.35	68.26
shift	+0.08	+0.09	+0.10	+0.11	+0.09	+0.09	+0.06	+0.07
F-PEA	142.85	137.99	737.93	723.99	630.00	618.51	69.19	68.11
shift	-0.07	-0.07	-0.14	-0.13	-0.09	-0.08	-0.10	-0.08
CF3-PEA	142.78	137.90	737.91	723.92	629.93	618.44	69.09	67.99
shift	-0.14	-0.16	-0.16	-0.20	-0.16	-0.15	-0.20	-0.20

Supplementary Table 6. Material parameters used for simulation in SCAPS-1D.

Parameter	Material		
	C ₆₀	Perovskite	NiO/SAM
Thickness (nm)	30	300	20
Bandgap (eV)	1.96	1.78	3.63
Electron Affinity (eV)	4.35	Various	1.56-1.96 (graded, exponential)
Dielectric permittivity (relative)	2.2	6	11.9 ¹⁰
Conduction band effective density of states (cm⁻³)	1E19 ¹¹	7.9E17 ¹²	2.5E18 ¹³
Valence band effective density of states (cm⁻³)	1E18	1E18 ¹²	1.8E18 ¹³
Electron mobility (cm²/Vs)	1E-2 ¹⁴	1.6E1 ¹⁵	1E-3
Hole mobility (cm²/Vs)	1E-2	1.6E1	1E-3
Shallow uniform acceptor density, N_A (cm⁻³)	0	1E15	1E18 ¹⁶
Shallow uniform donor density, N_A (cm⁻³)	1E17 ¹⁷	0	0
Defect type	-	Neutral	Neutral
Capture cross section (electrons) (cm⁻³)	-	1E-19	1E-15
Capture cross section (holes) (cm⁻³)	-	1E-19	1E-15
Energetic distribution	-	Single	Single
Energy level (eV)	-	0.5	0.5
Total defect density (cm⁻³)	-	1E15	1E14

Discussion of simulation parameters

Thickness: Thicknesses were chosen to reflect our device architecture

Bandgap: The bandgaps of C₆₀ and NiO_x were taken from UPS/IPES measurements and ¹⁸ respectively.

The bandgap of perovskite (1.78 eV) was taken from EQE measurements.

Electron affinity: The electron affinities of C₆₀ and NiO_x were taken from UPS measurements and ¹⁸ respectively. The electron affinity of the perovskite was determined from UPS/IPES measurements.

Dielectric permittivity: The dielectric permittivity of perovskite, NiO_x and C₆₀ were taken from ^{10,11,19} respectively.

Conduction/valence band effective density of states: The effective density of states for the conduction and valence bands (N_C and N_V respectively) were calculated using standard equations:

$$N_C = 2 \left(\frac{2\pi m_e^* kT}{h^2} \right)^{\frac{3}{2}}$$

$$N_V = 2 \left(\frac{2\pi m_h^* kT}{h^2} \right)^{\frac{3}{2}}$$

where k is Boltzmann's constant, T is temperature and h is Planck's constant. The effective masses of electrons and holes (m_e^* and m_h^* respectively) were found in the literature. For C₆₀, the value for electrons was taken from ¹¹ and for holes it was assumed to be the same as the absorber, an assumption used previously in ²⁰. For perovskite, values from ¹⁵ were used. For NiO_x, values from ¹³ were used.

Electron/hole mobilities: Mobilities for NiO_x are the same as used for the HTL layers in ²⁰. The electron and mobility of C₆₀ is taken from ¹⁴. Mobilities for perovskite are taken from ¹⁵.

Donor/acceptor densities: Our UPS results suggest that the perovskite is lightly p-type so have a low acceptor concentration of 1E15 cm⁻³. The hole concentration of NiO_x was taken from ¹⁶. The electron concentration of C₆₀ was taken to be 1E17 cm⁻³ similar to ¹⁷.

Bulk defects: Parameters concerning bulk defects were generated using the SCAPS standard settings which reflect real-world materials.²¹

Supplementary Table 7. Interface parameters used for simulation in SCAPS-1D.

Parameter	Interfaces	
	Perovskite/NiO _x	C ₆₀ /Perovskite
Defect type	Neutral	Neutral
Capture cross section (electrons) (cm⁻³)	1E-19	1E-19
Capture cross section (holes) (cm⁻³)	1E-19	1E-19
Energetic distribution	Single	Single
Energy level (eV)	0.5	0.5
Total defect density (cm⁻²)	1E12	1E15 – 1E14

Interface defects: Parameters concerning defects were generated using the SCAPS standard settings which reflect real-world materials. The total defect density (cm⁻³) for the perovskite/ETL interface was increased from the 1E10 generated by SCAPS to 1E+14 based on ¹⁷. For the perovskite HTL interface 1E12 was used, again using values from ²².

Supplementary Table 8. The TRPL of perovskite/C₆₀ junctions.

excitation fluences	5.83 nJ cm ⁻²		58.3 nJ cm ⁻²	
	τ_1 (ns)	τ_2 (ns)	τ_1 (ns)	τ_2 (ns)
Control	2.02	13.23	2.42	14.16
PEA	2.41	15.44	3.02	16.68
F-PEA	1.77	18.63	2.35	19.27
CF3-PEA	1.26	20.81	1.52	21.16

Supplementary Note 1: The enhanced J_{SC} of CF3-PEA.

The average J_{SC} increase of 0.5 mA cm^{-2} in CF3-PEA treated devices can be attributed to a complex combination of the following parameters: in CF3-PEA treated devices can be attributed to a complex combination of the following parameters: 1) sufficient contact of C_{60} layer with inorganic perovskite layer (*interaction strength in Fig. 1c*); 2) optimized interfacial energy level alignment (*energy level alignment diagram in Fig. 3f*), 3) decreased defect density (*steady-state PL intensity in Fig. 4a*) and 4) reduced ion movement^{23,24}.

Supplementary Note 2: A detailed description of the simulators

EnliTech (Class AAA) simulator was used for the $J-V$ measurements of single-junction PSCs, and the J_{SC} values can be easily corrected with a spectral mismatch factor.

SAN-EI ELECTRIC (XHS-50S1), a two-lamp simulator including Xe-lamp and halogen-lamp, was used for the $J-V$ measurement of tandem devices. The J_{SC} and FF values of tandem solar cells are sensitive to the spectrum of simulator²⁵. The spectral mismatch is within 2% at the wavelength range of 750-1100 nm, so we can get more accurate $J-V$ results for all-perovskite tandem solar cells.

Multi-color LED solar simulator (Class AAA) was used to test the long-term stability of PSCs. Xe-lamp maintenance life is typically around 1000 hours, and the light intensity gradually decreases with identical input voltage and current. Halogen-lamp has an even shorter life of 50-100 hours. Multi-color LED solar simulator (Class AAA) have a service life of greater than 10000 hours and can offer a stable spectrum for a long time. These features make LED simulator suitable for long-term stability tests at reasonable experimental costs.

Supplementary References

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Inorganic wide-bandgap perovskite subcells with dipole bridge for all-perovskite tandems

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Operating stability has become a priority issue for all-perovskite tandem solar cells. Inorganic $\text{CsPbI}_{3-x}\text{Br}_x$ perovskites, which have good photostability against halide segregation, are promising alternatives for all-perovskite tandem solar cells. However, the interface between organic transport layers and inorganic perovskite suffers from a large energetic mismatch and inhibits charge extraction compared with hybrid analogues, resulting in low open-circuit voltages and fill factors. Here we show that inserting at this interface a passivating dipole layer having high molecular polarity—a molecule that interacts strongly with both inorganic perovskite and C_{60} —reduces the energetic mismatch and accelerates the charge extraction. This strategy resulted in a power conversion efficiency (PCE) of 18.5% in wide-bandgap (WBG) devices. We report all-perovskite tandems using an inorganic WBG subcell, achieving a PCE of 25.6% (steady state 25.2%). Encapsulated tandems retain 96% of their initial performance after 1,000 h of simulated 1-sun operation at the maximum power point.

All-perovskite tandem solar cells consisting of wide-bandgap (WBG) perovskite (~1.8 eV) and narrow-bandgap (NBG) perovskite (~1.2 eV) absorber layers extend the usable range of the solar spectrum and reduce thermalization losses in single-junction solar cells^{1–4}. The highest reported power conversion efficiency (PCE) of all-perovskite tandem solar cells (26.4%) (ref. 5) has exceeded the best-performing single-junction perovskite solar cells (PSCs) (25.7%) (ref. 6); however, long-term stability remains a major bottleneck for commercial application, which requires a product lifetime of approximately 20–25 years (ref. 7).

A mixed iodine–bromine WBG perovskite is required in tandems to achieve a high open-circuit voltage (V_{oc}), yet photoinstability of WBG organic–inorganic hybrid perovskites limits long-term stability⁸. Efficient tandem devices made using a hybrid WBG layer have so

far maintained only >90% of initial PCE for 600 h of operation at their maximum power point (MPP)⁵. Inorganic $\text{CsPbI}_{3-x}\text{Br}_x$ perovskites exhibit increased photostability^{9–11} and excellent thermal stability, so they are good candidates for WBG absorbers^{12–14}. Despite this promise, the performance of all-inorganic PSCs, especially in the inverted p–i–n device structure, lags far behind organic–inorganic PSCs, a limitation dominated by low V_{oc} and fill factors (FF)^{15–19}, as listed in Supplementary Table 1.

We reasoned that fast crystallization with uncontrolled intermediate phases results in poor film quality for all-inorganic perovskites^{20–22}. The high density of interfacial defects leads to poor contact between the $\text{CsPbI}_{3-x}\text{Br}_x$ perovskite and electron-transport layers (ETL), which demands more effective passivation strategies. Another key challenge is that WBG $\text{CsPbI}_{3-x}\text{Br}_x$ perovskite has an inferior energetic alignment

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with ETL^{23,24}, especially for C₆₀ that is commonly used in the inverted architecture^{16,25}. Inorganic perovskites typically have higher conduction band minimums (CBM) than the equivalent hybrid perovskite at the same bandgap^{26–28}. The large conduction band offset ($\Delta E_c \approx 0.7$ eV) at this interface not only severely hinders charge extraction and leads to large V_{oc} losses^{29–31} but also triggers the hysteresis in the response of current density–voltage (J – V) curves³². Molecules with a π-conjugated backbone have the potential to passivate trap states and facilitate charge transfer^{33–36}. Organic passivators with an asymmetric structure can induce an intramolecular dipole moment across an interface owing to the unequal electronegativity.

In this Article, we find that introducing a dipole layer with high molecular polarity at the perovskite/C₆₀ interface reconfigures interfacial states to improve band alignment and increase the binding between inorganic perovskite and organic contacts. This strategy enables a PCE of 18.5% with a V_{oc} of 1.23 V and average FF > 0.83 and an operational stability for over 2,000 h without PCE degradation under 1-sun illumination in WBG PSCs. Using this all-inorganic WBG subcell, we report all-perovskite tandem solar cells with a PCE of 25.6%. Encapsulated tandem devices exhibit promising operating stability, maintaining 96% of their initial performance after over 1,000 h operation at MPP.

Molecular structure design strategy

Here we pursued a π-conjugated molecular structure to insert into perovskite/C₆₀ interface (Fig. 1a). Starting with the commonly used passivant phenethylammonium (PEA) cations, we seek to regulate the electric dipole moment by introducing either F atom (4-Fluorophenethylammonium (F-PEA)) or CF3 group (4-(Trifluoromethyl)phenethylammonium (CF3-PEA)) at the para position of the amino group (Fig. 1b and Supplementary Fig. 1). For this type of ammonium ligand, their $-NH_3^+$ side tends to interact with the perovskite surface^{37,38}, while the other side interacts with the C₆₀ contact layer. The maximum electrostatic potential (φ_{max}) at the $-NH_3^+$ side of each ligand is such that: $\varphi_{max,PEA} < \varphi_{max,F-PEA} < \varphi_{max,CF3-PEA}$; while the minimum electrostatic potential (φ_{min}) at the other side is: $\varphi_{min,PEA} > \varphi_{min,F-PEA} > \varphi_{min,CF3-PEA}$. We posited that the higher φ_{max} could increase the binding strength between the inorganic perovskite and passivator and that the lower φ_{min} could increase the binding strength between ETL and passivated perovskite layers. The large difference between φ_{max} and φ_{min} within a ligand usually suggests high molecular polarity. We found that the dipole moments for the neutral molecules increase as the number of electron-withdrawing F groups increases (Supplementary Table 2).

We carried out density functional theory (DFT) calculations to understand how the molecular structure of each passivator affects defect passivation and charge transport at the perovskite/ETL interface. Among the three passivation molecules, CF3-PEA binds to the perovskite most strongly by occupying the caesium vacancy site (Fig. 1c), in accordance with its highest φ_{max} when compared with PEA and F-PEA. A stronger binding with the perovskite surface suggests a more effective surface passivation because defective sites are more likely to be passivated. We revealed that in-gap states induced by deep-level defects, that is I-Pb antisites, are eliminated after passivation with PEA or CF3-PEA (Supplementary Fig. 2). The DFT simulation results herein indicate that better surface passivation enabled by CF3-PEA is mainly ascribed to stronger binding with defect sites on the perovskite surface.

To study how the passivating molecules affect interfacial charge transport, we explored the interaction between the C₆₀ layer and the perovskite surface and charge extraction at the perovskite/C₆₀ interface. As shown in Fig. 1d, capping passivators induce notable charge redistribution. Charge accumulation within C₆₀ molecules is repressed when passivated by PEA molecules and is further promoted in cases by F-PEA and CF3-PEA passivated perovskite. The adsorption energy (E_{ads}) of C₆₀ on the control (bare), PEA, F-PEA and CF3-PEA passivated (110) perovskite surfaces are -0.47 , -0.53 , -0.57 and -0.71 eV, respectively. This indicates that the interaction between C₆₀ and CF3-PEA

passivated perovskite is strongest among the three passivators, which reduces device charge transfer resistance and accelerates interfacial charge transfer³⁹.

We used the Heyd–Scuseria–Ernzerhof (HSE) including spin-orbital coupling (SOC) method to calculate the projected density of states (PDOS) of C₆₀/perovskite heterojunction (Fig. 1e). It can be found that these passivators (PEA, F-PEA and CF3-PEA) do not introduce sub-bandgap states. The CBM of the entire heterojunction originates from C₆₀ components. For the control and PEA passivated systems, the first conduction band (CB) of the perovskite component is far from the first CB of the C₆₀ component. However, for the CF3-PEA passivated system, the first two CBs become much closer in energy, and thus the CBMs of C₆₀ and perovskite align with each other. This indicates that electron extraction from the CF3-PEA passivated perovskite layer to the C₆₀ layer is more efficient than that in the control, PEA and F-PEA passivated cases⁴⁰.

We further studied the work function (WF) changes and CBM shifts upon three passivator treatments (Supplementary Table 3 and Supplementary Table 4). We found that F-PEA and CF3-PEA exhibit an increased WF and CBM downshift compared with the bare surface, while PEA exhibits a decreased WF and CBM upshift compared with the bare surface. The WF shift originates from two contributions^{41,42}, the intrinsic dipole of the ligands ($\mu_{intrinsic}$) and the dipole created by the interaction between the ligands and the perovskite surface ($\mu_{interaction}$). $\mu_{intrinsic}$ and $\mu_{interaction}$ lie in opposite directions along the z axis of the surface slabs and thus have an opposite effect on the WF. Because PEA has a lower molecular polarity, its $\mu_{intrinsic}$ contribution was less than that of F-PEA and CF3-PEA and therefore insufficient to negate the WF decrease contributed by the $\mu_{interaction}$ term, resulting in an overall WF decrease. We thus offer that in cationic-type passivated cases, a higher molecular polarity helps to induce a WF increase and improve electron extraction.

Photovoltaic performance of CsPbI_{3-x}Br_x PSCs employing dipole layers

DFT calculations indicated that CF3-PEA has the potential to provide more effective surface passivation and improved interfacial electron extraction than conventional PEA. To test this idea, we fabricated all-inorganic CsPbI_{3-x}Br_x PSCs in the inverted p-i-n architecture to evaluate the effects of the three passivators on photovoltaic (PV) performance, and the preparation process is shown in Supplementary Fig. 3. The optimized concentration in isopropanol (IPA) of PEA, F-PEA and CF3-PEA were all 1.0 mol% relative to Cs⁺ (Supplementary Fig. 4). Figure 2a and Table 1 compare the PV parameters of the control and passivated solar cells. Prototypical passivator PEA improved V_{oc} slightly but reduced the short-circuit current density (J_{sc}) and FF, resulting in only a slight improvement in PCE. Encouragingly, F-PEA and CF3-PEA substantially improved the V_{oc} and FF of devices without deteriorating J_{sc} .

Champion devices using CF3-PEA exhibited V_{oc} up to 1.23 V, a gain of 220 mV compared with control devices. Accompanied with a noticeable FF improvement (80.7% to 82.8%) and high J_{sc} (18.1 mA cm⁻²), the champion CF3-PEA device achieved a high PCE of 18.5%, the highest value for inverted all-inorganic perovskite with a bandgap around 1.8 eV. The steady-state PCE of the CF3-PEA device is 18.3% (Supplementary Fig. 5), well matched with the PCE determined from J – V scans. The J_{sc} calculated from external quantum efficiency (EQE) agrees well with the value from J – V measurement (Fig. 2b). Supplementary Fig. 6 shows the PCE histogram of 120 CF3-PEA passivated devices with an average PCE of 17.3% and a narrow distribution with standard deviation of 0.49%. The hysteresis index (defined as $(PCE_{reverse} - PCE_{forward}) / PCE_{reverse} \times 100\%$) of control, PEA, F-PEA and CF3-PEA devices are 13.9%, 11.1%, 4.0% and 3.0%, respectively (Fig. 2c). The CF3-PEA device had the lowest hysteresis (PCEs of 18.5% vs 18.0% between reverse and forward scans), which is good compared with that of high-performance all-inorganic PSCs reported previously^{43,44}. This we attribute to defect

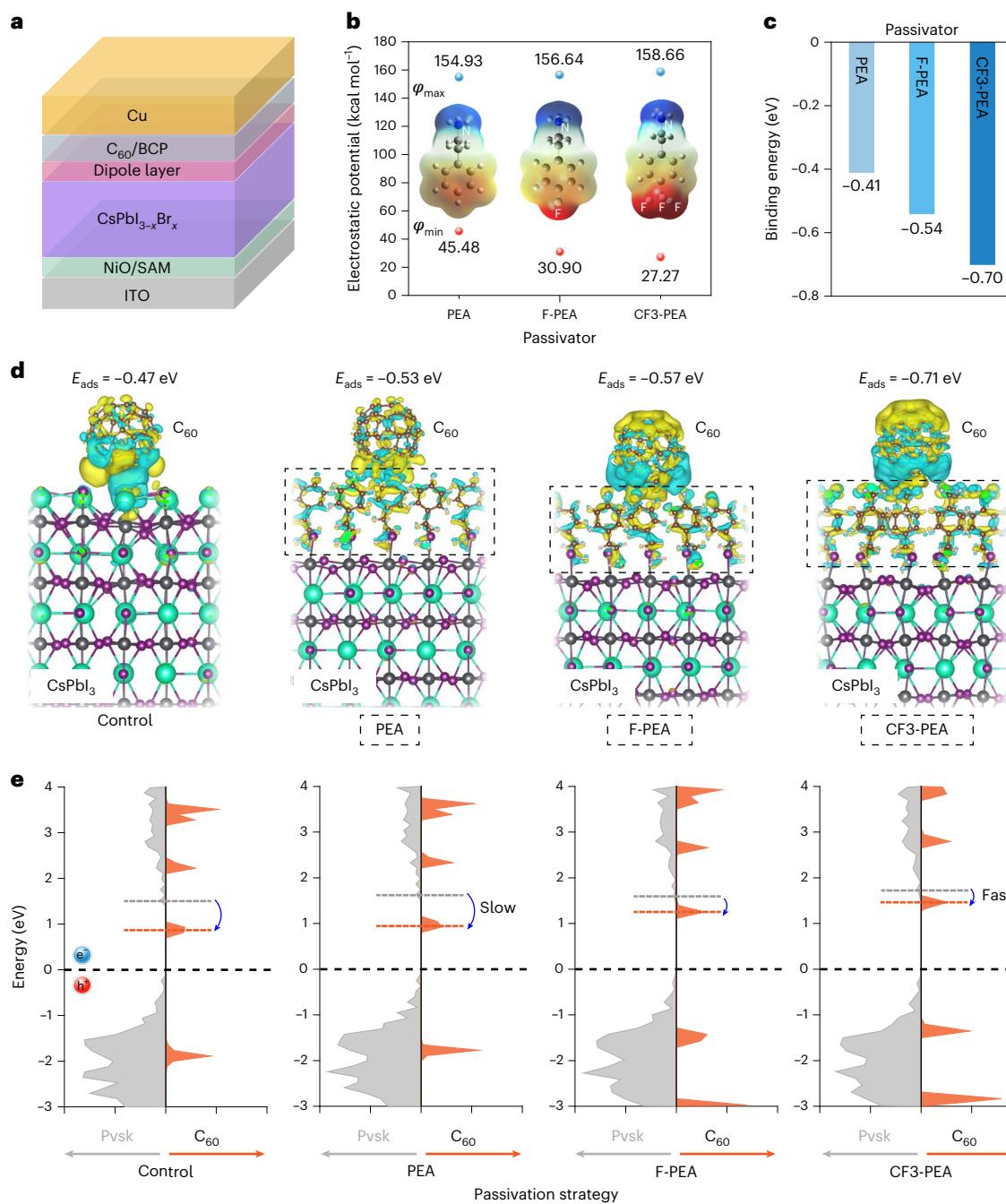


Fig. 1 | Density functional theory calculations of surface passivation and interfacial charge transport. **a**, Schematic structure of inverted $\text{CsPbI}_{3-x}\text{Br}_x$ PSCs. BCP, bathocuproine; SAM, self-assembled monolayer; ITO, indium tin oxide. **b**, Electrostatic potentials (φ) (φ_{max} : blue colour; φ_{min} : red colour) of each passivator (PEA, F-PEA and CF3-PEA). **c**, Binding energy between passivators and V_{Cs} defects for an Cs-I terminated (001) perovskite surface. **d**, Charge density difference (blue, depletion; yellow, accumulation) of anchoring C₆₀ ETL onto the control and ammonium cation (PEA, F-PEA and CF3-PEA) passivated (110) perovskite surfaces. The same isosurface level is used. Calculated adsorption energies (E_{ads}) are also shown. The passivation molecules are shown in the dashed

black box. The atoms in the structures are differentiated by different colours: Cs is represented by grass green, Pb by grey and I by purple. **e**, HSE + SOC calculated PDOS of the perovskite/C₆₀ heterojunction for each passivation strategy. The grey and orange dashed lines indicate the first CB levels of perovskite and C₆₀ at the interface, respectively. Pvk: perovskite, e⁻: electron, h⁺: hole. The grey and orange arrows indicate the PDOS area of the perovskite layers and C₆₀ layers, respectively. The blue arrow denotes the direction of electron transport at the perovskite/C₆₀ interface. 'Fast' and 'Slow' labels indicate the fast/slow electron extraction property.

passivation by CF3-PEA and improved band alignment at the perovskite/C₆₀ interface^{45,46}, a trend also seen in DFT.

We investigated the operational stability of all-inorganic $\text{CsPbI}_{3-x}\text{Br}_x$ PSCs using a multi-colour LED solar simulator with intensity equivalent to 100 mW cm⁻² by continuously tracking the MPP in ambient conditions. The encapsulated CF3-PEA device maintained its initial

PCE during 2,000 h of MPP operation (Fig. 2d). We studied the role, in achieving higher photostability, of the all-inorganic $\text{CsPbI}_{3-x}\text{Br}_x$ films vs the effect of the dipole layer. Both the control and CF3-PEA-treated devices did not show any light-induced phase segregation after 20 minutes of 10-sun equivalent illumination. In contrast, organic-inorganic hybrid perovskite films with a similar bandgap exhibited serious phase

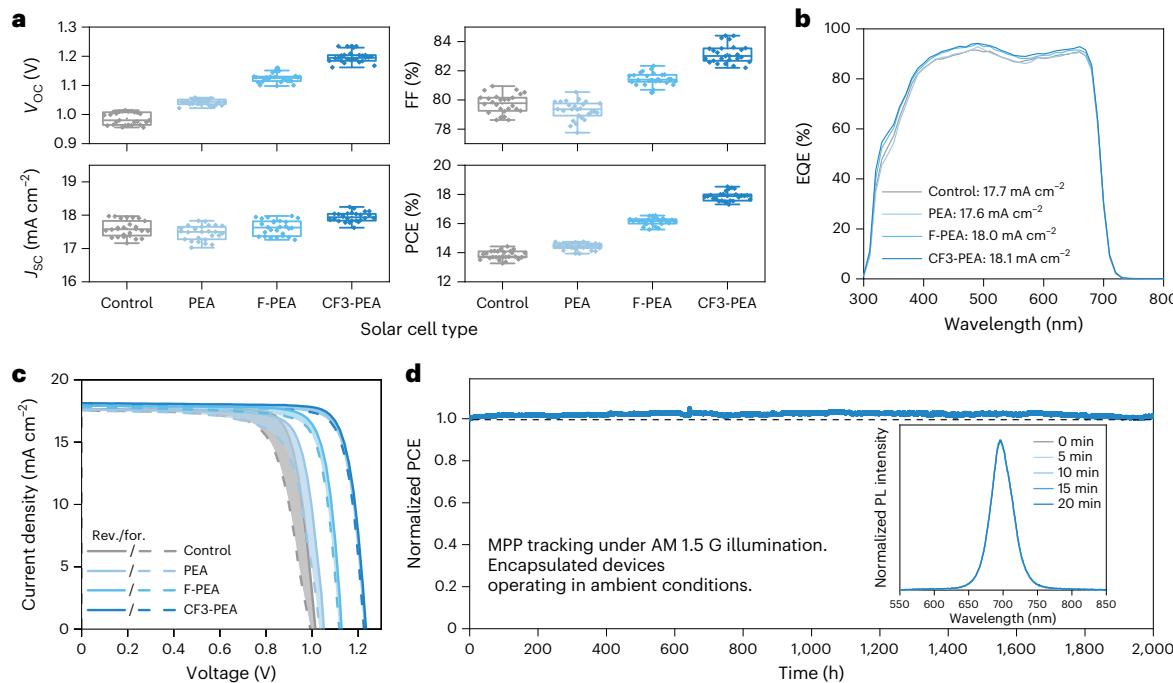


Fig. 2 | PV performance of $\text{CsPbI}_{3-x}\text{Br}_x$ perovskite solar cells with dipole layers. **a**, PV parameters of control and passivated solar cells (26 devices for each type). The box plot denotes median (centre line), 75th (top edge of the box) and 25th (bottom edge of the box) percentiles. The solid dots represent each device datum. **b**, EQE curves of the four champion devices. **c**, J - V curves of the four champion devices for each condition. Rev., reverse scan; for., forward scan. J - V hysteresis performance was represented by the shaded area. **d**, MPP tracking

of an encapsulated CF3-PEA device for over 2,000 h in air under simulated 1-sun solar illumination (equivalent to AML5 G, 100 mW cm^{-2} , multi-colour light-emitting diode (LED) simulator). The device had an initial PCE of 16.8%. The operating temperature of the device was around 35°C , and the relative humidity was approximately 30–40%. The inset shows PL spectra of CF3-PEA film under 10-sun illumination for 0, 5, 10, 15 and 20 min.

Table 1 | PV parameters of the control and passivated PSCs

Device	Scans	V_{oc} (V)	J_{sc} (mA cm^{-2})	FF (%)	PCE (%)	SPO (%)	HI (%)
Control	Reverse	1.01	17.6	80.7	14.4	13.4	13.9
	Forward	0.99	17.5	71.4	12.4		
	Average	0.99 ± 0.02	17.6 ± 0.24	79.7 ± 0.64	13.8 ± 0.29		
PEA	Reverse	1.05	17.6	79.6	14.7	13.9	11.1
	Forward	1.03	17.6	72.3	13.1		
	Average	1.04 ± 0.01	17.5 ± 0.22	79.3 ± 0.62	14.4 ± 0.23		
F-PEA	Reverse	1.13	18.0	81.7	16.5	16.1	4.0
	Forward	1.12	17.8	79.7	15.9		
	Average	1.12 ± 0.02	17.6 ± 0.22	81.4 ± 0.41	16.1 ± 0.25		
CF3-PEA	Reverse	1.23	18.1	82.8	18.5	18.3	3.0
	Forward	1.23	18.0	81.4	18.0		
	Average	1.20 ± 0.02	18.0 ± 0.14	83.2 ± 0.62	17.9 ± 0.32		

Average rows: the values represent the average and standard deviation of 26 devices under reverse scan. SPO, stabilized power output; HI, hysteresis index.

separation under identical illumination conditions (Fig. 2d inset and Supplementary Fig. 7). The inorganic PSCs also had higher thermal stability than do the organic-inorganic hybrid devices under 85°C thermal stress (Supplementary Fig. 8 and Supplementary Fig. 9).

Characterization of $\text{CsPbI}_{3-x}\text{Br}_x$ perovskite films

Next we sought to characterize the morphology and crystalline structure of $\text{CsPbI}_{3-x}\text{Br}_x$ perovskite films to reveal the interaction between perovskites and passivators. Scanning electron microscopy (SEM) images show dense, pinhole-free control films; the morphologies of films are unchanged after passivation (Fig. 3a). Passivation

treatments did not affect the overall crystallinity and no new phase was formed, as evidenced by X-ray diffraction (XRD) patterns (Fig. 3b). If the concentration of passivators increased, we found peaks at low angles ($2\theta < 10^\circ$) appear, which correspond to diffraction signals of the original molecules (Supplementary Fig. 10). Once we used IPA to wash the high-concentration capping layers, all of these impurity XRD peaks disappeared. These results indicate that the passivators do not form 2D perovskite capping layers⁴⁷, something we assign to the strong resistance of Cs^+ to ion exchange, which is consistent with previously reported results^{48,49}. The thin passivation layers also did not alter UV-vis absorption, and the band edges remain

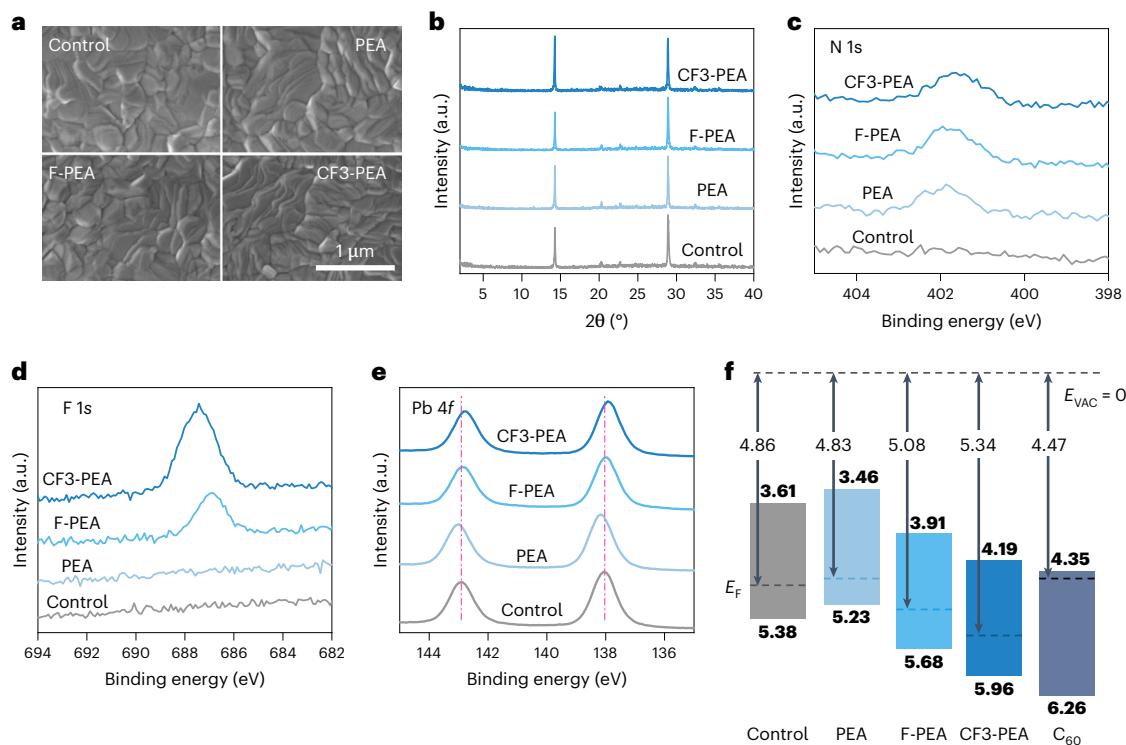


Fig. 3 | Characterization of $\text{CsPbI}_{3-x}\text{Br}_x$ perovskite films. **a**, SEM images of perovskite films. **b**, XRD patterns of perovskite films. **c–e**, XPS spectra of N 1s (**c**), F 1s (**d**) and Pb 4f (**e**) core level. The vertical dashed lines indicate the binding energy position of Pb 4f in the control film. **f**, Energy-level alignment diagram

of $\text{CsPbI}_{3-x}\text{Br}_x$ and ETL. E_F : Fermi level, E_{VAC} : vacuum level. The vertical arrows indicate the work function (WF) with respect to the E_{VAC} . The horizontal dashed lines indicate the E_F in the film. The bold text: the CBMs and VBM in the films. The regular text: the WF values.

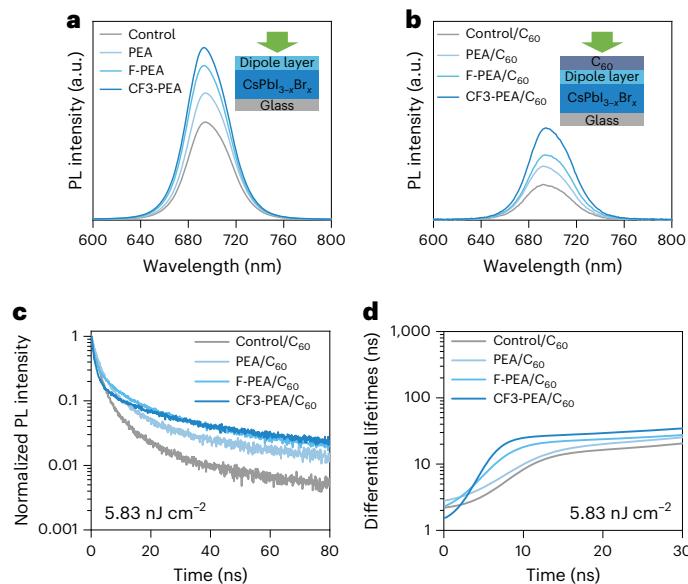


Fig. 4 | PL properties of perovskite films with different dipole layers. **a,b**, Steady-state PL spectra of perovskite films (**a**) and perovskite films coated with C₆₀ (**b**). The insets show the sample structures and the laser illumination directions. **c**, TRPL spectra of perovskite/C₆₀ junctions. **d**, Computed differential lifetimes obtained by taking the derivative from fits to the transients in **c**. The excitation fluence of TRPL spectra was 5.83 nJ cm⁻².

The elemental composition and electronic structure for the pristine and passivated $\text{CsPbI}_{3-x}\text{Br}_x$ films are determined by X-ray photoelectron spectroscopy (XPS) measurement. The XPS spectra of N 1s and F 1s shown in Fig. 3c,d indicate the existence of the passivator molecules on the surface of passivated films. The Pb 4f XPS spectrum of the control film contains two main peaks at 138.06 eV and 142.92 eV, corresponding to the Pb 4f_{7/2} and 5/2 orbitals, respectively. The Pb 4f peaks in the PEA passivated film shift towards higher binding energy by 0.08 eV, whereas the F-PEA and CF3-PEA passivated films shift to lower binding energies by 0.07 eV and 0.14 eV (Fig. 3e), respectively. The XPS core level spectra of Cs 3d, I 3d and Br 3d in perovskite are shown in Supplementary Fig. 13. The shift direction of binding energy for elements (Pb/Cs/I/Br) show the same trend, though the shift values are slightly different (Supplementary Table 5). In perovskite films with each passivator, the binding energy shift of Cs is the largest among characterized elements, indicating that the passivators have a stronger interaction with Cs^{31,33}.

We further performed ultraviolet photoelectron spectroscopy (UPS) to investigate the surface energetics of perovskite films and C₆₀ layers (Supplementary Fig. 14 and Supplementary Fig. 15). From UPS we can see that PEA treatment decreases the WF of $\text{CsPbI}_{3-x}\text{Br}_x$ film surfaces from 4.86 to 4.83 eV with respect to the vacuum level, while F-PEA and CF3-PEA passivated films exhibit deeper WFs of 5.08 eV and 5.34 eV, respectively (Fig. 3f). The ΔE_C between the CBM of $\text{CsPbI}_{3-x}\text{Br}_x$ and pure C₆₀ (4.35 eV) for control, PEA-, F-PEA- and CF3-PEA-treated films are 0.74, 0.89, 0.44 and 0.16 eV, respectively. We also provide the estimated energetics of C₆₀ coated on different passivation perovskite films (Supplementary Fig. 16). The energy-level alignment was presented as referenced to the vacuum level and Fermi level (E_F), respectively (Supplementary Fig. 17). We found that the PEA enlarges the ΔE_C between the perovskite and C₆₀, while the F-PEA and CF3-PEA dipole layers reduce the ΔE_C offset, which is consistent with the results

nearly unchanged (~1.77 eV) (Supplementary Fig. 11). The PV bandgap estimated from the EQE spectra is about 1.78 eV (ref. 50) (Supplementary Fig. 12), which is comparable with the optical bandgap value of 1.77 eV (Supplementary Fig. 11).

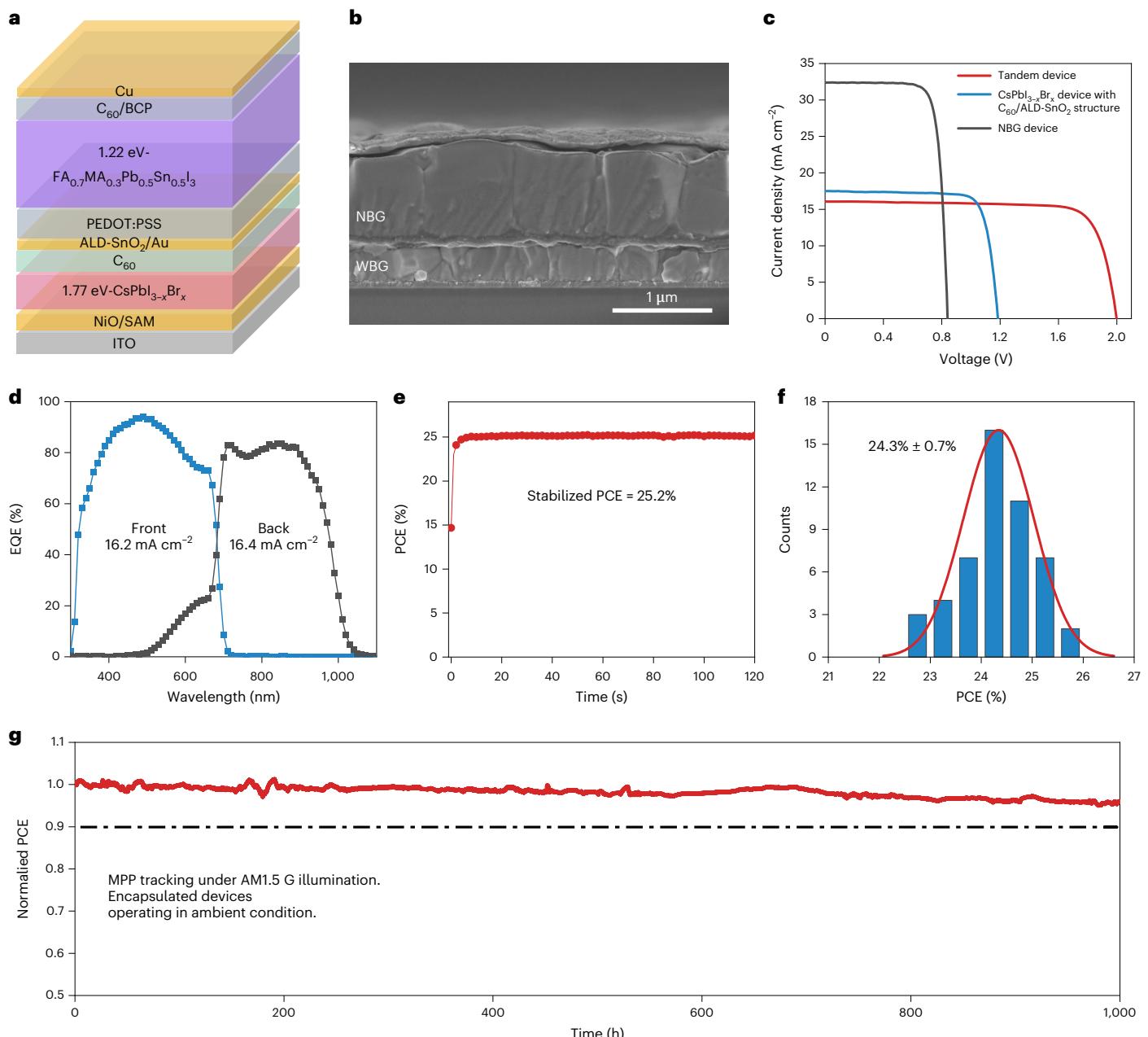


Fig. 5 | Performance of monolithic all-perovskite tandem solar cells. **a,b**, Schematic structure (**a**) and cross-sectional SEM image (**b**) of an all-perovskite tandem solar cell. PEDOT, PSS: poly(3,4-ethylene dioxythiophene)-poly(styrene sulfonate). **c**, The *J*–*V* measurements from a CsPbI_{3-x}Br_x single-junction device with C₆₀/ALD-SnO₂ structure, a FA_{0.7}MA_{0.3}Pb_{0.5}Sn_{0.5}I₃ NBG device and a monolithic all-perovskite tandem cell. **d**, EQE curves of the best-performing tandem cell. **e**, Stabilized power output of the champion tandem

cell. **f**, Histogram of PCEs over 50 all-perovskite tandem solar cells, showing an average PCE of 24.3 ± 0.7%. **g**, Continuous MPP tracking of an encapsulated tandem cell over 1,000 hours under simulated 1-sun illumination (equivalent to AM1.5 G, 100 mW cm⁻², multi-colour LED simulator) in ambient air. The device had an initial PCE of 24.1%. The operating temperature of the device was around 35 °C, and the relative humidity was approximately 30–40%.

obtained from separately measured C₆₀ on top of glass/ITO. Our DFT calculations also support above experimental results of the WF changes and CBM shift upon three passivator treatments.

Drift-diffusion modelling shows that the approximately 210 mV V_{OC} increase in CF3-PEA-treated devices can be linked to a reduced energy-level mismatch between perovskite and ETL (ΔEc) and trap passivation at the perovskite surface. When we vary the surface trap density, ΔEc presents the dominant effect. The model indicates that ΔEc affects V_{OC} in two ways: increased recombination at the perovskite/C₆₀ interface, which reduces quasi Fermi level splitting (QFLS), and losses

purely related to band alignment where the V_{OC} is lower than the bulk QFLS (Supplementary Fig. 18).

We measured the ideality factor of devices using each treatment (Supplementary Fig. 19); values of the control, PEA, F-PEA and CF3-PEA devices were 1.32, 1.25, 1.22 and 1.17, respectively. Reduced ideality factor of devices indicates suppressed non-radiative recombination. We measured the electroluminescence spectra of control and passivated PSC devices, operating as LEDs (Supplementary Fig. 20). The CF3-PEA-passivated devices achieved significantly higher electroluminescence intensity at various applied bias. Combined with the

Table 2 | Champion PV parameters of the WBG subcell with C₆₀/ALD-SnO₂ structure, the NBG subcell and the all-perovskite tandem device

Device	V _{oc} (V)	J _{sc} (mA cm ⁻²)	FF (%)	PCE (%)
WBG subcell (with ALD-SnO ₂)	1.19	17.5	80.6	16.6
NBG subcell	0.84	32.4	79.7	21.7
Tandem	2.00	16.1	79.6	25.6

lowest ideality factors for the CF3-PEA passivated device, we confirm that CF3-PEA exhibits the most efficient suppression of trap-assisted recombination in devices among these three passivators.

We performed steady-state photoluminescence (PL) and time-resolved photoluminescence (TRPL) to probe the radiative recombination and carrier transfer behaviour in CsPbI_{3-x}Br_x films. The passivated CsPbI_{3-x}Br_x films exhibit suppressed defect-induced non-radiative recombination, as evidenced by the increased PL intensities (Fig. 4a). As shown in Fig. 4b, the CF3-PEA film coated with C₆₀ shows PL enhancement, indicating the C₆₀ does not induce as much recombination as it does for the control. This is due to passivation of surface defects and the band mismatch between the C₆₀ and the perovskite surface. The PEA device is not worse than the control (bigger mismatch) because the QFLS of films does not decrease beyond a mismatch of approximately 0.3 eV. And then the PEA film has a lower defect density. Figure 4c presents TRPL of perovskite/C₆₀ junctions, from which we calculated the differential lifetime (Fig. 4d) to distinguish charge extraction vs trap-assisted recombination. The first interval at shorter times is dominated by the transfer of electrons from the bulk into the C₆₀, and the second interval at longer delay times is dominated by interfacial recombination^{51–53}. The sharp drop in emission for CF3-PEA/C₆₀ indicates efficient electron transfer at the interface, and the high plateau suggests a reduced trap density. We obtained the same trend under an increased excitation fluence of 58.3 nJ cm⁻² (Supplementary Fig. 21 and Supplementary Table 8). Drift-diffusion modelling shows that the maximum achievable J_{sc} based on absorption is 18.4 mA cm⁻², assuming that all absorbed photons contribute to the current (Supplementary Fig. 18d). CF3-PEA-treated devices show an average J_{sc} increase of 0.5 mA cm⁻² compared with control devices (Supplementary Note 1).

Performance and stability of all-perovskite tandems

We then fabricated monolithic all-perovskite tandem solar cells using CF3-PEA passivated CsPbI_{3-x}Br_x perovskite for the WBG subcells (Fig. 5a,b). The champion tandem device exhibited a PCE of 25.6% under reverse scan with a V_{oc} of 2.00 V, J_{sc} of 16.1 mA cm⁻² and FF of 79.6% (Fig. 5c and Table 2). The integrated J_{sc} values of the WBG and NBG subcells from EQE spectra are 16.2 and 16.4 mA cm⁻², respectively, in good agreement with the J_{sc} values determined from J-V measurements (Fig. 5d). The champion tandem device exhibited a stabilized PCE of 25.2% measured over 120 s (Fig. 5e). Figure 5f shows the PCE histogram of 50 tandem solar cells processed among several batches, indicating an average PCE of 24.3% and a good reproducibility. The photovoltaic performance of tandem solar cells with all-inorganic WBG subcells is comparable to that of tandem devices with inorganic–organic hybrid WBG perovskites reported in our previous studies^{54,55}.

We found that the performance of CsPbI_{3-x}Br_x PSCs slightly reduced in V_{oc} and FF after replacing the C₆₀/BCP-based ETL with C₆₀/ALD-SnO₂(ALD-SnO₂; SnO₂ using atomic layer deposition), required in all-perovskite tandem solar cells (Supplementary Fig. 22). The performance reduction of devices with the ALD-SnO₂ layer could be explained by the following factors: (1) the approximately 100 minute-long heating at 75 °C during ALD processing possibly altered the metastable state of the all-inorganic perovskites⁵⁶; (2) the vacuum environment

during ALD may accelerate the phase transition of all-inorganic perovskites⁵⁷; (3) the moisture injected during water pulses could be harmful to all-inorganic perovskites, of which the phase is very sensitive to moisture^{48,58}.

Device stability is crucial for the commercialization of all-perovskite tandems. We investigated long-term operational stability under simulated 1-sun illumination. We tracked the power output of encapsulated devices at their MPP in ambient air under a multi-colour LED solar simulator with intensity equivalent to 100 mW cm⁻². The tandem devices exhibit promising operational stability and maintained 96% of initial PCE after MPP operation over 1,000 h (Fig. 5g), which is superior to the tandem devices with mixed-cation and mixed-halide hybrid WBG perovskites in previous reports^{59,60}.

The inorganic WBG perovskites enable a substantial advance in operating stability, yet work remains to be done to increase the PCEs of all-perovskite tandem devices. To achieve PCEs beyond 30%, the V_{oc} of the WBG front subcell must improve from 1.23 V reported here to greater than 1.4 V, something that may be obtained by further suppressing bulk and surface recombination. Regulating the rapid nucleation and crystallization process of all-inorganic perovskite films with additive and composition engineering is expected to reduce the bulk trap density. Higher V_{oc} is further expected by reducing the hole transport layer/perovskite interfacial recombination losses. Another focus will be on further improving the phase stability of WBG inorganic perovskites, something enabled by composition engineering, to avoid performance degradation in front subcells during the sequent deposition steps of the tunnel recombination junction and NBG bottom subcells. We project that by combining such efforts, it will become possible to achieve PCEs of all-perovskite tandem solar cells that reach towards those of hybrid subcells.

Conclusions

This work demonstrates efficient and stable all-perovskite tandem solar cells with an all-inorganic WBG subcell that provides improved photostability over hybrid perovskites. We demonstrate a strongly bonding electric dipole interlayer using high-polarity CF3-PEA molecules to passivate surface defects and regulate interfacial energy-level alignment, resulting in suppressed non-radiative charge recombination and improved interfacial electron extraction. Using the CF3-PEA passivator, inverted all-inorganic CsPbI_{3-x}Br_x PSCs show a PCE of 18.5% with excellent operating stability over 2,000 h. We further achieve an efficiency of 25.6% (steady state 25.2%) in an all-perovskite tandem solar cell using a CsPbI_{3-x}Br_x WBG subcell. The encapsulated tandem devices retain 96% of their initial performance after 1,000 h of simulated 1-sun illumination. This 1,000-h lifetime appears to surpass—by fully a factor of four times—the longest-operating lifetime reported in all-perovskite tandem cells⁵. The strategy contributes a facile route towards efficient and stable all-perovskite tandem solar cells.

Methods

First-principles calculations

First-principles calculations based on density functional theory (DFT) were carried out using the Vienna Ab initio Simulation Package⁶¹. For the exchange-correlation functional, the Perdew–Burke–Ernzerhof functional⁶² and the screened Heyd–Scuseria–Ernzerhof (HSE) hybrid functional^{63,64} were adopted. In addition, DFT-D3 method was used for the van der Waals correction⁶⁵. The spin-orbital coupling (SOC) effect was included. The mixing parameter (α) of the Hartree–Fock term in HSE + SOC calculations was set to 0.45, which had been proven to reproduce the experimental bandgap. The plane-wave cut-off energy was 400 eV. The energy and force convergence criteria were set to 10⁻⁵ eV and 0.03 eV Å⁻¹, respectively. The Brillouin zone was sampled with Γ-centred k-mesh densities of $2\pi \times 0.03 \text{ \AA}^{-1}$ in the calculations of the energetic and electronic properties. We used a vacuum of 20 Å to separate neighbouring surfaces in the z direction. The binding

energies of different ammonium cations (PEA, F-PEA and CF3-PEA) with the perovskite surface were calculated as $E_{\text{mol}/\text{pvsk}} - E_{\text{pvsk}} - E_{\text{mol}}$, where $E_{\text{mol}/\text{pvsk}}$, E_{pvsk} and E_{mol} are the total energies of the adsorption system, the perovskite system and CF3-PEAI/F-PEAI/PEAI (I represents iodide), respectively. A higher binding energy value indicates a stronger binding strength with the perovskite surface. The adsorption energies (E_{ads}) of C_{60} with different ammonium cations (PEA, F-PEA and CF3-PEA) passivated and bare perovskite surface were calculated as $E(\text{C}_{60}@\text{perovskite}) - E(\text{C}_{60}) - E(\text{perovskite})$. The electrostatic potentials (φ) of the passivators were calculated in the Gaussian 09 package at the B3LYP/def2TZVP level with DFT-D3. The maximum φ (φ_{max}) and minimum φ (φ_{min}) in these passivators were obtained with the help of Multiwfn code⁶⁶.

Drift-diffusion modelling for device-performance simulation

We used SCAPS-1D (a solar cell capacitance simulator) to build the device model⁶⁷. Detailed simulation methods are illustrated in Supplementary Fig. 18 and Supplementary Tables 6 and 7.

Materials

All materials were used as received without further purification. PbI_2 (99.99%), PbCl_2 (99.99%), PbBr_2 (99.99%), 2PACz ([2-(9H-carbazol-9-yl)ethyl]phosphonic acid) (>98.0%) and MeO-2PACz ([2-(3,6-dimethoxy-9H-carbazol-9-yl)ethyl]phosphonic acid) (>98.0%) were purchased from TCI Chemicals. SnI_2 (99.999%) was purchased from Alfa Aesar. SnF_2 (99.9%), formamidine sulfinic acid (FSA, ≥ 98%), CsI (99.999%), DMF, (99.8% anhydrous), DMSO (99.9% anhydrous), isopropanol (IPA, 99.8% anhydrous) and ethyl acetate (99.8% anhydrous) were purchased from Sigma-Aldrich. The organic halide salts (FAI, MAI, DMAI, PEAI, F-PEAI) were purchased from GreatCell Solar Materials. CF3-PEAI (99.9%) and BCP (>99% sublimed) were purchased from Xi'an Polymer Light Technology Corp. PEDOT:PSS aqueous solution (Al 4083) was purchased from Heraeus Clevios. The C_{60} was purchased from Nano-C. NiO nanocrystals were synthesized according to previous reports⁶⁸.

Perovskite precursor solution

For WBG $\text{CsPbI}_{3-x}\text{Br}_x$ perovskite, DMAI:CsI: $\text{PbBr}_2:\text{PbI}_2:\text{PbCl}_2$ (molar ratio = 0.9:1:0.45:0.55:0.1) were dissolved in mixed DMF and DMSO solvents (volume ratio = 1:1.4) at a concentration of 0.95 M and were stirred at 60 °C in a N_2 glovebox for 2 h before film fabrication. The precursor solution was filtered through a 0.22 μm polytetrafluoroethylene (PTFE) membrane before making the perovskite films.

For NBG $\text{FA}_{0.7}\text{MA}_{0.3}\text{Pb}_0\text{Sn}_{0.5}\text{I}_3$ perovskite, the precursor solution (2.0 M) was prepared in mixed solvents of DMF and DMSO with a volume ratio of 2:1. The molar ratios for FAI/MAI and $\text{PbI}_2/\text{SnI}_2$ were 0.7:0.3 and 0.5:0.5, respectively. The molar ratio of (FAI + MAI)/($\text{PbI}_2 + \text{SnI}_2$) was 1:1. SnF_2 (10 mol% relative to SnI_2) was added in the precursor solution. The precursor solution was stirred at room temperature for 2 h. Tin powders (5 mg ml^{-1}) and FSA (0.3 mol%) were added in the precursor to reduce Sn^{4+} in the precursor solution. The precursor solution with the remaining tin powders was filtered through a 0.22 μm PTFE membrane before making the perovskite films.

All-inorganic perovskite solar cell fabrication

The pre-patterned ITO glass was sequentially washed with water, acetone and IPA sequentially and then treated with UV-ozone for 15 min before use. The NiO layer was spin coated onto the ITO substrate with a NiO nanocrystal suspension (20 mg ml^{-1} in water) at 3,000 r.p.m. for 30 s and subsequently annealed at 100 °C for 10 min in air. Self-assembled molecules (SAM) were used to optimize the NiO film⁶⁹. The solutions of 2PACz and MeO-2PACz with the same concentration (0.2 mmol l^{-1} in IPA) were mixed with 1:3 ratio and then were spin coated on the NiO film at 4,000 r.p.m. for 20 s, followed by annealing at 100 °C for 5 min. After cooling, the substrates were immediately transferred to the glovebox. The perovskite precursor was spin coated

on NiO/SAM at 2,600 r.p.m. for 150 s and was kept in the N_2 glovebox for 1 h before heating. The samples were then taken out from the glovebox and annealed at 170 °C for 20 min in ambient air with a humidity below 40%. For surface passivation, the passivation solution in IPA (1 mol%) was drop cast on perovskite film at 5,000 r.p.m. for 20 s, followed by drying at 90 °C for 3 min. Then the cooled films were washed by IPA at 5,000 r.p.m. for 20 s. After the cooling to room temperature, the substrates were transferred to the evaporation system. Finally, C_{60} (20 nm), BCP (7 nm) and Cu (100 nm) were sequentially deposited on top of the perovskite by thermal evaporation.

Monolithic all-perovskite tandem solar cell fabrication

The $\text{CsPbI}_{3-x}\text{Br}_x$ films were prepared as mentioned above. The substrates were transferred to the evaporation system after the fabrication of all-inorganic perovskite films, and 20-nm-thick C_{60} film was deposited on top by thermal evaporation at a rate of 0.2 Å s^{-1} . The substrates were then transferred to the atomic layer deposition (ALD) system (Veeco Savannah S200) to deposit 20 nm SnO_2 at 75 °C using precursors of tetrakis(dimethylamino) tin(IV) (99.999%, Nanjing Ai Mou Yuan Scientific Equipment Co.) and deionized water. After ALD deposition, the substrates were transferred back to the thermal evaporation system to deposit an ultra-thin layer of Au clusters layer (~1 nm) on ALD- SnO_2 . PEDOT:PSS layers were spin cast on top of front cells and annealed in air at 120 °C for 20 min. After the substrates had cooled, we immediately transferred the substrates to a nitrogen-filled glovebox for the deposition of NBG perovskite films. The perovskite films were deposited with two-step spin-coating procedures: (1) 1,000 r.p.m. for 10 s with a ramp up of 200 r.p.m. s^{-1} and (2) 4,000 r.p.m. for 40 s with a ramp up of 1,000 r.p.m. s^{-1} . Ethyl acetate (200 μl) was dropped on the spinning substrate during the second spin-coating step at 20 s before the end of the procedure. Finally, 20 nm C_{60} , 7 nm BCP and 150 nm Cu films were sequentially deposited by thermal evaporation (Beijing Technol Science). Details on the deposition of ALD- SnO_2 layers can be found in our previous work⁵⁵.

Characterization of solar cells

For single-junction solar cells, the $J-V$ characteristics were measured using a Keithley 2400 sourcemeter under the illumination of the solar simulator (EnliTech, Class AAA) at the light intensity of 100 mW cm^{-2} as checked with National Renewable Energy Laboratory (NREL)-calibrated reference solar cells (KG-5 and KG-0 reference cells were used for the measurements of WBG and NBG solar cells, respectively). Unless otherwise stated, the $J-V$ curves were all measured under the same conditions⁷⁰ in a nitrogen-filled glovebox with a scanning rate of 200 mV s^{-1} (voltage steps of 20 mV and a delay time of 100 ms). The active area was determined by the aperture shade mask (0.049 cm^2) placed in front of the solar cells. EQE measurements were performed in ambient air using a QE system (EnliTech) with monochromatic light focused on device pixel and a chopper frequency of 20 Hz. For tandem solar cells, the $J-V$ characteristics were carried out under the illumination of a two-lamp high-spectral-match solar simulator (SAN-EI ELECTRIC, XHS-50S1). The spectrum from the simulator was finely tuned to ensure that spectral mismatch is within $100 \pm 3\%$ for each 50-nm interval between wavelength range 400 nm and 1,000 nm. The solar simulator was set at the light intensity of 100 mW cm^{-2} as checked with a calibrated crystalline silicon reference solar cell with a quartz window (KG-0) (detailed discussion in Supplementary Note 2). EQE measurements were performed in ambient air, and the bias illumination from highly bright LEDs with emission peaks of 850 nm and 460 nm were used for the measurements of the front and back subcells, respectively. No bias voltage was applied during the EQE measurements of tandems.

Operational stability tests of solar cells

The operating stability tests were carried out under simulated AM1.5 G illumination (Class AAA, multi-colour LED solar simulator, Guangzhou

Cryscor Equipment Co.) with an intensity of 100 mW cm^{-2} using a home-built LabVIEW-based MPP tracking system and a perturb and observe method in ambient conditions (humidity of 30–50%). The solar cells were encapsulated with a cover glass and UV epoxy (Three Bond), which was cured under an UV-LED lamp (peak emission at 365 nm) for 3 min. No UV filter was applied during operation. The MPP ageing was performed at room temperature, and the device temperature was increased to around 35–40 °C during operation due to the self heating under illumination. There was no active cooling during the measurement stage. The illumination intensity was regularly calibrated to check the degradation of the LED lamp.

Other characterizations

XRD patterns were acquired using a Bruker D8 AVANTAGE Diffractometer with Cu K α ($\lambda = 1.54 \text{ \AA}$) radiation. XPS analysis was carried out using the Thermo Scientific Al K-Alpha XPS system with energy steps of 0.1 eV. SEM images were obtained using a TESCAN microscope with an accelerating voltage of 2 kV. Optical absorption measurements were carried out in a Lambda 950 UV/Vis spectrophotometer.

PL measurements were conducted on a home-built wide-field microscope based on Olympus IX73. A 532 nm diode laser was used as the excitation light for the sample measurements with the laser power density on the film surface of 100 mW cm^{-2} . The fluorescence of the samples was collected by a dry objective lens (Olympus LUCPlanFI 40 \times , Numerical Aperture (NA) = 0.6) and detected by an Electron Multiplying Charge-Coupled Device (EMCCD) camera (iXon Ultra 888, Andor) after passing through 550 nm (ET550LP, Chroma) long-pass filters. TRPL was measured using a Horiba Fluorolog-3 time-correlated single photon counting system; the samples were excited using a pulsed laser with a wavelength of 485 nm (2 MHz, 5.83 nJ cm^{-2} and 58.3 nJ cm^{-2}) from the glass side. The PL decay curves were fitted with biexponential components to obtain a fast and a slow decay lifetime.

Ultraviolet photoelectron spectroscopy (UPS) was performed in an ultrahigh vacuum surface analysis system equipped with a fast entry load lock, a transfer chamber and an analysis chamber (base pressure approximately 10^{-10} mbar). UPS employed the He I 21.22 eV as the excitation source with an energy resolution of 50 meV. The work function was derived from the secondary electron cut-off and the ionization potential from the frontier edge of the occupied density states to the vacuum level. The LED device characterizations were carried out with a Keithley 2400 source meter and a 100 mm integrating sphere coupled with a spectrometer (Ocean Optics, Spectrum TEQ-EQY).

Reporting summary

Further information on research design is available in the Nature Portfolio Reporting Summary linked to this article.

Data availability

The datasets generated and analysed during the current study are included in the published article and its Supplementary Information and source data files. Source data are provided with this paper.

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Author contributions

H.T. conceived the idea and directed the overall project. T.L. and C.D. fabricated all the inorganic perovskite devices and conducted the characterization. J. Xu carried out the DFT simulation. S.T. performed SCAPS simulations. K.X. helped on ALD processing. R.L. and P.W. helped on the fabrication of NBG subcells. S.J., S.X. and Q.B. performed the UPS measurements. H. Li, Z.L., B.C., H. Luo, S.W., Y.T., L.L., X.G. and J. Xie helped on the material characterization. H.T. and E.H.S. supervised the work. H.T., T.L. and J. Xu wrote the draft paper, and S.T., H. Li, Q.Z., B.C., L.L., X.G. and E.H.S. improved the paper. All authors read and commented on the paper.

Competing interests

Hairen Tan is the founder, chief scientific officer and chairman of Renshine Solar Co., Ltd., a company that is commercializing perovskite PVs. The other authors declare no competing interests.

Additional information

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Solar Cells Reporting Summary

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► Experimental design

Please check: are the following details reported in the manuscript?

1. Dimensions

Area of the tested solar cells

Yes
 No

The "Characterization of solar cells" of "Methods"

Method used to determine the device area

Yes
 No

The "Characterization of solar cells" of "Methods"

2. Current-voltage characterization

Current density-voltage (J-V) plots in both forward and backward direction

Yes
 No

Figure 2c

Voltage scan conditions

For instance: scan direction, speed, dwell times

Yes
 No

The "Characterization of solar cells" of "Methods"

Test environment

For instance: characterization temperature, in air or in glove box

Yes
 No

Figure captions and "Characterization of solar cells" of "Methods"

Protocol for preconditioning of the device before its characterization

Yes
 No

These devices are tested directly without any preprocessing.

Stability of the J-V characteristic

Verified with time evolution of the maximum power point or with the photocurrent at maximum power point; see ref. 7 for details.

Yes
 No

Figure 5e and Supplementary Figure 5

3. Hysteresis or any other unusual behaviour

Description of the unusual behaviour observed during the characterization

Yes
 No

Section "PV performance of CsPbI_{3-x}Br_x PSCs employing dipole layers"

Related experimental data

Yes
 No

Figure 2c and Table 1

4. Efficiency

External quantum efficiency (EQE) or incident photons to current efficiency (IPCE)

Yes
 No

Figure 2b and Figure 5d

A comparison between the integrated response under the standard reference spectrum and the response measured under the simulator

Yes
 No

The integrated J_{sc} values from QE were consistent with J_{sc} values from J-V measurements.

For tandem solar cells, the bias illumination and bias voltage used for each subcell

Yes
 No

The "Characterization of solar cells" of "Methods"

5. Calibration

Light source and reference cell or sensor used for the characterization

Yes
 No

The "Characterization of solar cells" of "Methods"

Confirmation that the reference cell was calibrated and certified

Yes
 No

The "Characterization of solar cells" of "Methods"

<p>Calculation of spectral mismatch between the reference cell and the devices under test</p> <p>6. Mask/aperture</p> <p>Size of the mask/aperture used during testing</p> <p>Variation of the measured short-circuit current density with the mask/aperture area</p> <p>7. Performance certification</p> <p>Identity of the independent certification laboratory that confirmed the photovoltaic performance</p> <p>A copy of any certificate(s) <i>Provide in Supplementary Information</i></p> <p>8. Statistics</p> <p>Number of solar cells tested</p> <p>Statistical analysis of the device performance</p> <p>9. Long-term stability analysis</p> <p>Type of analysis, bias conditions and environmental conditions <i>For instance: illumination type, temperature, atmosphere humidity, encapsulation method, preconditioning temperature</i></p>	<p><input type="checkbox"/> Yes <input checked="" type="checkbox"/> No</p> <p>The light spectrum used for measurements matches well with the reference silicon cell, and we did not calculate the spectral mismatch between the reference cell and the tested devices</p> <p><input checked="" type="checkbox"/> Yes <input type="checkbox"/> No</p> <p>The "Characterization of solar cells" of "Methods"</p> <p><input type="checkbox"/> Yes <input checked="" type="checkbox"/> No</p> <p>We measured all devices with masks.</p> <p><input type="checkbox"/> Yes <input checked="" type="checkbox"/> No</p> <p>The focus of this paper is to improve the stability of tandems using an inorganic wide-bandgap subcell. In addition, the reliability of the two-lamp high spectral match solar simulator (SAN-EI ELECTRIC, XHS-50S1) has been confirmed, so the certification is not necessary for this work.</p> <p><input type="checkbox"/> Yes <input checked="" type="checkbox"/> No</p> <p>No certificate</p> <p><input checked="" type="checkbox"/> Yes <input type="checkbox"/> No</p> <p>Stated in the manuscript.</p> <p><input checked="" type="checkbox"/> Yes <input type="checkbox"/> No</p> <p>Stated in the manuscript.</p> <p><input checked="" type="checkbox"/> Yes <input type="checkbox"/> No</p> <p>The "Operational stability tests of solar cells" of "Methods"</p>
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